

SR STANDARD

C8800

144MHz TRANSCEIVER

INSTRUCTIONS MANUAL



STANDARD COMMUNICATIONS CORP.

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We are confident that you will be entirely satisfied with your 144 MHz Transceiver Model C8800. Our very strict quality control and inspection ensure that each transceiver unit left the factory in perfect condition. If the unit is damaged or fails to operate properly, immediately contact your dealer.

To obtain the best performance and longest use from your transceiver, study these instructions carefully.

ACCESSORIES

* Hand microphone with freq. up-down control (MP-716)	1
* DC power cord	1
* Stand	1
* Mobile bracket	1
* Nine-pin plug	1
* Bracket mounting screw	1
* Operation handbook	1
* Schematic diagram	1

INSTRUCTION MANUAL SECTION

1. PRECAUTIONS

■ INSTALLATION PRECAUTIONS

1. Install your transceiver in a dry, dust-free and well-ventilated place. The unit should not be subjected to extremely high temperatures or humidity. It must not, under any circumstances, be exposed to direct sunlight.
2. Provide adequate space behind and under the unit for free circulation of air.
3. In a mobile installation, exercise special care to allow enough space behind the unit for adequate heat-dissipation from the heat sink. Take measures to ensure that the unit is not subjected to excessive vibration or shock during operation.

■ POWER SUPPLY

1. The C8800 is designed to operate on 13.8 volt DC or commercial AC power. Do not connect this unit to a 24 volt DC power supply (E.g., batteries used in large vehicles).

The transceiver is equipped with an internal memory back-up system. For further details of the system, read paragraph 4.2.4.

2. When you wish to power your transceiver from a commercial AC outlet, use the operationally available power Supply Attachment.

■ ANTENNA

To obtain the best results from the C8800 Transceiver, use an antenna which has a proven performance. The SWR of your antenna should be adjusted to 1.5 or below. If SWR adjustment is inadequate, the transmission power may fail to reach the specified value.

If the antenna SWR is increased to more than 4 or 5, an internal protection circuit automatically operates to reduce transmission power and protect final transistors.

2. FEATURES

The C8800 Mobile Transceiver features innovative micro-computer-aided operations. The C8800's built-in micro-computer memorizes, thinks, and makes decisions for quick and correct channel control.

The microcomputer offers the following functions:

1. Capable of memorizing, or programming any five (5) frequencies (max.).
2. Scans up and down the five stored channel frequencies.
3. Scans up and down the five stored channels plus two call channels.
4. Scans up and down frequencies from 144.00 MHz through 145.995 MHz at a 5 kHz or 25 kHz interval.
5. Automatically searches for busy channels.
6. Automatically searches for vacant channels.
7. Two switchable scanning speeds are provided.
8. Two frequency-scanning intervals of 5 kHz and 25 kHz are provided.
9. A higher priority is given to the two call channels (145.50 MHz and 145.55 MHz).

■ SUPERIOR OPERABILITY AND MANY OTHER FEATURES

- **Memory back-up feature:**
With this feature, pre-programmed channel frequencies are maintained in the memory even when the main power to the unit is switched OFF. If the supply voltage is abnormally low, an internal DC-to-DC converter initiates operation to maintain the back-up voltage at a constant level, to keep the stored frequency data intact.
- **400 channels selectable:**
Up to 400 channels can be selected using the non-contact channel selector which has 24 steps per rotation (80 channels at 25 kHz interval, and 400 channels at 5 kHz interval).
- **Microphone with a frequency up-down control:**
The attached hand microphone was a built-in frequency up-down control for easy and continuous channel selection.
- **Easy-to-operate, sloping control panel:**
The C8800 is designed ergonomically and features a sloping control panel for ease of operating controls and a carefully thought out panel layout.

■ OTHER FEATURES

- A built-in receiver booster with three-stepped reception sensitivity control for DX operation.
- Built-in general call frequency of 145.50 MHz and mobile call frequency of 145.55 MHz available.
- A unique signal & power meter comprised of 9 LEDs.
- Easy-on-the-eyes, 4 digit green LED frequency read-out.
- Superior intermodulation characteristic achieved with the introduction of the herical cavity.
- Large 8 cm ϕ built-in loudspeaker.
- A line-noise filter shuts out any noise on the AC power line.
- A single VCO serving for both reception and transmission.
- Transmission power switchable between 1 watt and 10 watts.
- The "direct" VCO circuit reduces generation of spurious noise.
- The APC (Auto Power Control) circuit protects final transistors from variations of antenna SWR or supply voltage.

- The mic-amplifier uses the VOGAD IC, which permits modulation of a high mean-modulation degree and low distortion.
- A piezo-electric buzzer for audible checking incorporated on keyboard and UP/DWN control operations.
- Built-in tone burst generator for repeater driving.
- Built-in frequency-shift circuit for repeater.

3. PANEL FEATURES

■ FRONT PANEL FEATURES



① SENS (Sensitivity) SELECTOR

The SENS selector is used for reception sensitivity selection (DX, NOR, and LOC positions). The DX position is for long-distance communication, the NOR position for middle-distance communication, and the LOC position for local communication.

② PUSH TONE/SQEL (Squelch) CONTROL

This knob serves a dual purpose: squelch control and tone-burst switch. While this knob is depressed, the transmitter transmits a tone-burst signal for repeater driving (Tone frequency: 1750 Hz). The squelch control is used to eliminate white noise heard on FM reception channels when no signals is present. Normally, this control should be turned gradually clockwise until the white noise disappears.

③ PUSH ON/VOL CONTROL

This knob also serves a dual purpose: power switch and volume control. A first depression of this knob turns the power to the unit ON, and the second depression turns it OFF. Clockwise rotation of this control increases output volume level.

④ PWR SELECTOR

The PWR selector selects transmission power between 1 watt and 10 watts. The 1W position of this switch will be found to be best for local communication.

⑤ CHANNEL SELECTOR

Clockwise rotation of this selector increases channel frequency at either a 5 kHz or 25 kHz interval.

⑥ MEMO ENTER BUTTON

Pressing this button stores the desired frequency data in the internal memory. The memory has a capacity for storing up to 5 frequencies.

Use the CHANNEL selector or the UP/DWN control on the microphone to preset the desired frequency before pressing this MEMO ENTER button.

⑦ MHz BUTTON

A simple depression of this button switches the frequency band from 144 MHz to 145 MHz and vice versa.

⑧ MEMO RCL BUTTON

Pressing this button recalls stored frequency data. Each depression of this button recalls stored frequencies sequentially from M1 through M5.

⑨ RPT (Repeater) BUTTON

This key is used to select Simplex, Repeater-1, Repeater-2, or Repeater-3.

⑩ SCAN ALL BUTTON

While this button is depressed, the entire 144 MHz or 145 MHz frequency band is scanned at a 5 kHz or 25 kHz interval.

⑪ CALL BUTTON

The CALL button gives priority in frequency selection to call frequencies 145.50 MHz and 145.55 MHz. The first depression of this button selects 145.50 MHz, and the second depression selects 145.55 MHz.

⑫ SCAN MEMO BUTTON

Pressing this button initiates scanning stored frequencies sequentially from M1 through M5. If the CALL key is depressed before this SCAN MEMO button is depressed, the CALL channel frequencies C1 and C2 (145.50 MHz and 145.50 MHz, respectively) can be added to the scanning sequence, thus establishing a new sequence C1 - C2 - M1 - M2 - M3 - M4 - M5.

⑬ CCL BUTTON

Pressing the CCL button resets operation mode to the initial state.

⑭ SCAN MODE SWITCH

This switch is used to search for busy or vacant channels during frequency scanning. The BUSY position of this switch initiates a search for busy channels, and the VACANT position a search for vacant channels.

⑮ SCAN SPEED SWITCH

This switch is used to select frequency scanning speeds:
HI position: 0.25 second per step
LOW position: 2.0 second per step

⑯ MIC JACK

The MIC jack accepts the attached hand microphone.

⑰ SIGNAL & POWER METER

This unique 9-LED meter indicates signal strength in the reception mode, and transmission power in the transmission mode.

⑱ R1 (Repeater-1) INDICATOR

When this R1 indicator is lit, the transmission frequency is reduced by 600 kHz with respect to the reception frequency. If transmission is tried at a frequency below 144,600 MHz, the transmitter output is shut down and the frequency readout displays "OFF".

⑲ R2 (Repeater-2) INDICATOR

When this R2 indicator is lit, the transmission frequency is increased by 600 kHz with respect to the reception frequency. If transmission is tried at a frequency above 145,400 MHz, the transmitter output is shut down and the frequency readout displays "OFF".

⑳ R3 (Repeater-3)

- By providing an optional quartz crystal in the C8800's PLL circuit, transmission frequency can be shifted arbitrarily with reference to the readout frequency (received frequency). The shifted transmission frequency is, however, not displayed.
- When no crystal is provided in the circuit, the transmitter section remains inoperative while the receiver section operates at the readout frequency.
- For details of the required quartz crystal specifications, see paragraph "X'tal for Repeater-3".

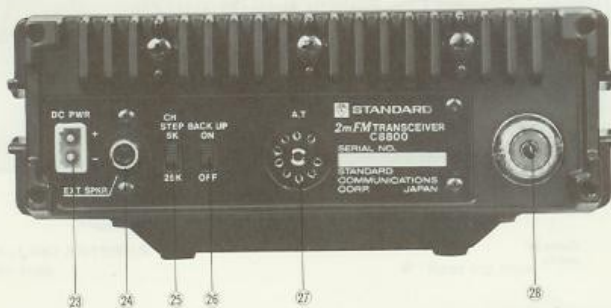
㉑ FREQUENCY READOUT

When a signal of, say, 145.50 MHz is received, this frequency readout displays the last four digits as "5.500". If the CALL button is depressed, the least significant digit of the readout is replaced with "C" to indicate that the CALL function is activated.

㉒ STAND

The unit can be placed on the stand when it is operated as a fixed station.

■ REAR PANEL FEATURES



㉓ DC 13.8 V

This receptacle accepts a DC 13.8 V power supply. Connect the supplied connection cord with care to ensure the correct polarity.

㉔ EXT SPKR JACK

This jack accepts an external speaker with an impedance of 4~8 ohms.

㉕ CH STEP SWITCH

The CH STEP switch is used to select a single frequency step interval of either 5 kHz or 25 kHz.

㉖ BACK-UP SWITCH

Activating this switch provides the internal memory with a back-up power supply to maintain stored frequency

data even when the main power to the unit is switched OFF. If the transceiver unit is left unused for a long period of time, be sure to set this switch at the OFF position.

㉗ A.T. (Accessory Terminal)

For details of the pin configuration of this terminal, refer to the paragraph "Accessory Terminal".

㉘ ANT CONNECTOR

The ANT connector accepts an antenna with an impedance of 50 ohms.

■ HAND MICROPHONE

㉙ FREQ. UP-DOWN CONTROL

This control initiates continuous up and down scanning of channel frequencies.

㉚ PTT BUTTON

Pressing this PTT (Press-To-Talk) button puts the transceiver in the transmission mode.



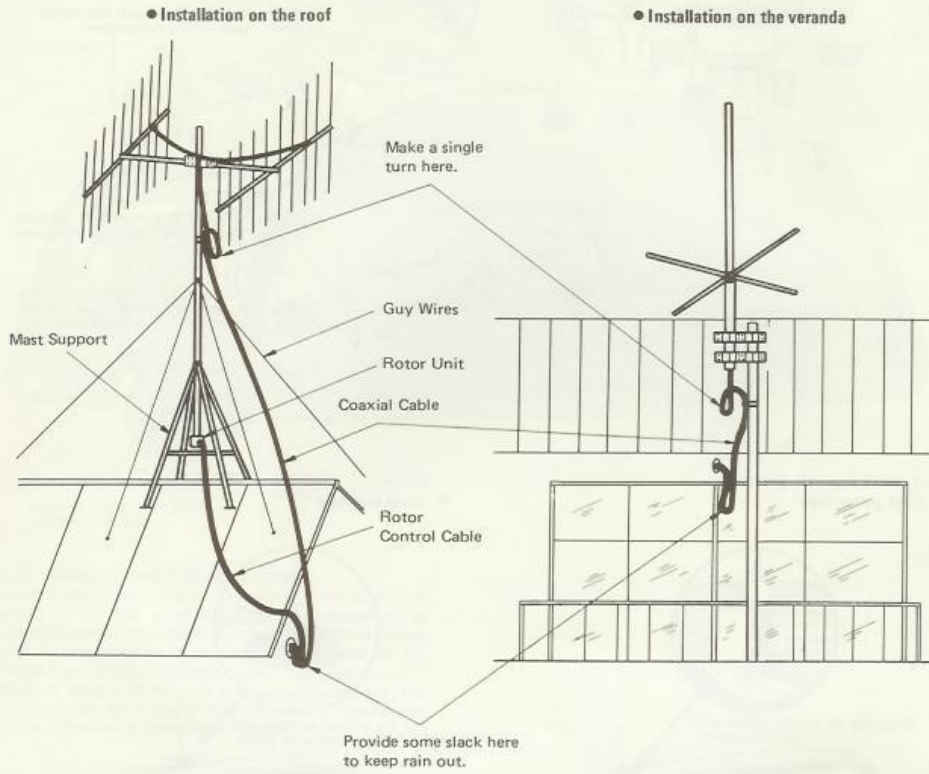
4. INSTALLATION

4.1 FIXED STATION

4.1.1 INSTALLING THE ANTENNA

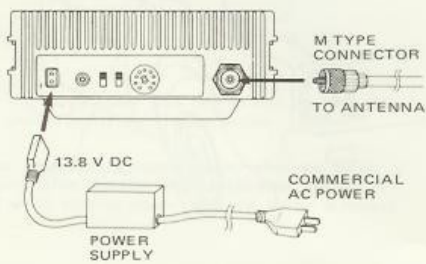
The type and method of installation of the outdoor antenna you use will greatly affect transmission and reception performances of your transceiver. Carefully select an antenna which will provide the best performance, and adjust carefully after installation.

To prevent lead-in signal loss, use as short an antenna lead-in cable as possible. Recommended cable type is the 5D-2V for up to 10 meters, and the 8D-2V or 10D-2V for up to 30 meters.



4.1.2 POWER SUPPLY

When supplying power from the wall outlet, use the power supply unit (optional accessory).

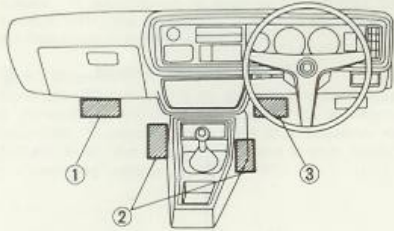


4.2 MOBIL TRANSCEIVER

4.2.1 INSTALLING THE TRANSCEIVER

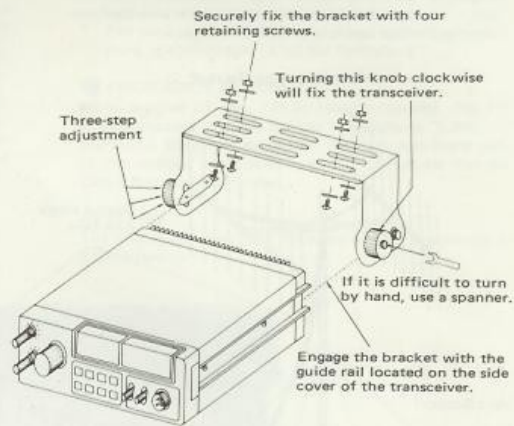
■ Installation position

- ① Below glove box
- ② Beside center console box
- ③ Below the dashboard



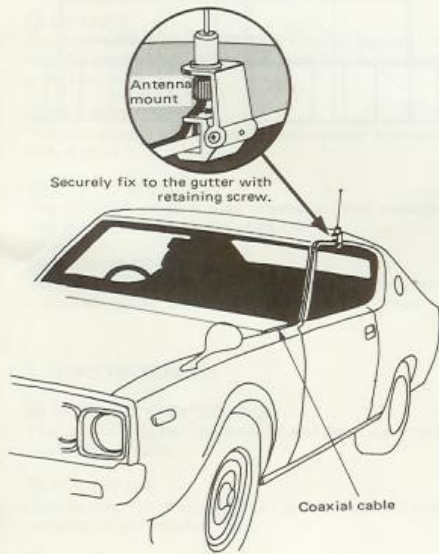
■ Installing with bracket (provided)

With the bracket, the receiver can be positioned freely and the angle of the transceiver can be changed in three steps.



4.2.2 INSTALLING ANTENNA

■ Roof gutter type

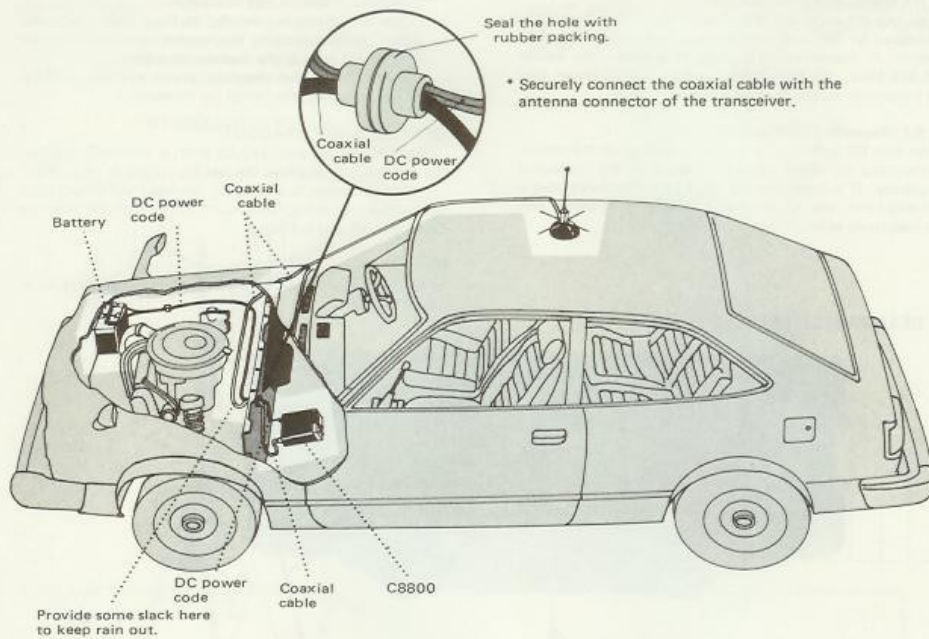


■ Roof top type



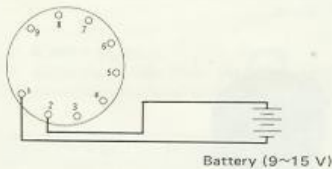
4.2.3 CONNECTING THE COAXIAL CABLE

■ Routing through the bonnet



4.2.4 CONNECTING THE POWER CODE

Connect the power code to the battery. If the BACK UP switch on the rear plate is turned ON, the memory is not erased when the C8800 is turned OFF. If the power cord is connected to a wire which is coupled to the engine key, the BACK UP switch does not function. When a battery (9~15 V) is connected between the 1P (Gnd) and 2P(+) of the ACC terminal, turning ON the BACK UP switch will retain the memory.



NOTE:

Fix the coaxial cable with tape so that the cable does not come in contact with the hot engine.

Some lines do not supply power when the starter is rotated. After checking with a multimeter, connect to a line which supplies power when the starter is rotated.

5. MICROCOMPUTER-AIDED OPERATION

The following section of the manual gives you a description of the microcomputer-aided operation of your transceiver unit in some detail.

5.1 PRECAUTIONS

The C8800 VHF Transceiver is capable of transmitting varied types radio waves. Use utmost care to avoid any trouble in comfort to your local regulations.

2m Band Plan (L.A.R.U. Region 1)

MHz	Allocation
144.000-144.010	E-M-E
144.050	CW calling
144.100	CW random ms
144.150	Upper limit CW exclusive
144.200	SSB random ms
144.300	SSB calling
144.500	SSTV calling
144.600	RTTY calling
144.700	FAX calling
144.900	Regional beacons centre
145.000-145.225	Repeater input - R0 to R9
145.300	RTTY (local)
145.500	Mobile calling
145.500 (S20), 145.525 (S21)	FM simplex
145.550 (S22), 145.575 (S23)	FM simplex
145.600-145.825	Repeater output or Output



NOTES:

1. Established simplex frequencies on repeater output channels may be retained.
2. The segment 145.250-145.500 MHz may be allocated, if desired, to FM channels.
3. No regional planning for beacons of erp less than 50 W.
4. Regional planning for beacons of erp more than 50 W.
5. CW permitted over v-hole band, CW exclusive 144.0-144.150 MHz.
6. Channelized nets should not operate in this portion at any time.
7. Local traffic should operate above 145 MHz during contents and band openings.

Table 1. VHF Band Plans

5.2 MICROCOMPUTER OPERATION

(1) SELECTING SCANNING INTERVALS

The desired frequency scanning of either 5 kHz/step or 25 kHz/step is selected with the STEP switch on the rear of the unit.

(2) PWR AND BACK-UP SWITCHES

- a. When the power to the unit is turned ON, the internal microcomputer program first selects a channel frequency of 145.00 MHz.
- b. When the unit is powered directly from your car battery, turning OFF the power to the unit with the BACK UP switch set to ON will cause the microcomputer to store the state immediately before the power is turned OFF, and when the power to the unit is again turned ON, the unit restores the state immediately before the power was turned OFF (the scanning condition is, however, not memorized).

(ex.) 1. When channel frequency is set to 145.525 MHz:

5.525 → Power OFF →

Power ON → 5.525

2. When channel frequency is set to 5.50c:

5.50c → Power OFF →

Power ON → 5.50c

(3) FREQUENCY SELECTION

Channel frequencies can be selected with the CHANNEL selector on the front panel of the unit or with the UP-DOWN control on the Hand Microphone.

* Channel selection using the UP-DOWN control on the mic:

- a. The Hand Microphone (MP-716) supplied with the C8800 Transceiver is equipped with a channel frequency UP-DOWN control. Pressing and holding the control switch in the UP or DOWN position scans the channels.
- b. When the UP-DOWN switch is released, the channel scan stops at the frequency currently being received.
- c. Holding the UP-DOWN control switch for less than 0.5 second shifts channel scan to the next channel where it stops.
- d. While the UP-DOWN control switch is activated, all other key operations are disabled, except for the Press-To-Talk (PTT) button on the microphone which stops channel scanning.
- e. When the [ALL], [MEMO], or [CALL] button is depressed, the UP-DOWN control switch is ineffective. While the transceiver is operating in the transmission mode, the UP-DOWN control switch is also ineffective.

(4) HOW TO PROGRAM CHANNEL FREQUENCIES

A. Initial frequency programming
The C8800 incorporates five memory units M1, M2, M3, M4, and M5 each capable of storing up to one frequencies i.e. five frequencies in all. To store the desired frequency in each memory unit, follow the procedure given below:

Storing frequency data in memory M1

- a. Press key **[RCL]** to recall the content of memory M1. (Before the key is pressed, the frequency readout will read "145.000 MHz".)
When memory is vacant:

5.000.

Blinks

(The dot at bottom left of LSD will blink to indicate that memory M1 is vacant).

- b. Tune to the desired frequency by moving the **CHANNEL** selector on the front panel of the unit or the **UP-DOWN** control on the Hand Microphone. (E.g. 145.025 MHz)
The display will read:

5.025.

Blinks

- c. Pressing the **[ENTER]** key stores the frequency data in memory M1.

5.025.

Lights up

- d. Press the **[RCL]** key again to check the frequency data stored in memory M1.

5.025.

Storing frequency data in memory M2

- a. Pressing the **[RCL]** key again will display the content of memory M2.
When memory M2 is vacant:

5.025.

Blinks

- b. Tune to the frequency to be stored in M2 with the **CHANNEL** selector or **UP-DOWN** control. (E.g. 145.050 MHz).

5.050.

Blinks

- c. Press the **[ENTER]** button to store the frequency data in memory M2.

5.050.

Lights up

- d. Press the **[RCL]** key to check the frequency data stored in memory M1.

5.025.

- e. Press the **[RCL]** key again to check the frequency data stored in memory M2.

5.050.

Storing frequency data in memory M3

- a. Press the **[RCL]** button to display the content of memory M3 to the frequency readout.
When memory M3 is vacant:

5.050.

Blinks

- b. Tune to the frequency to be stored in M3 with the **CHANNEL** selector or **UP-DOWN** control. (E.g. 145.075 MHz).

5.075.

Blinks

- c. Press the **[ENTER]** button to store the frequency data in memory M3.

5.075.

Lights up

- d. Press the **[RCL]** button to check the frequency data stored in memory M1.

5.025.

- e. Press the **[RCL]** button again to check the frequency data stored in memory M2.

5.050.

- f. Press the **[RCL]** button a third time to check the content of memory M3.

5.075.

Storing frequency data in memory M4

- a. Press the **[RCL]** button to display the content of memory M4.

5.075.

Blinks

- b. Tune to the desired frequency to be stored in M4 by controlling the **CHANNEL** selector or **UP-DOWN** control. (E.g. 145.100 MHz)

5.100.

Blinks

- c. Press the **[ENTER]** button to store the frequency data in memory M4.

5.100.

Lights up

d. Press the **[RCL]** button to check the content of M1.

5.025

e. Press the **[RCL]** button again to check the content of memory M2.

5.050

f. Press the **[RCL]** button once again to check the content of M3.

5.075

g. And finally press the **[RCL]** button a fourth time to check the content of M4.

5.100

Storing frequency data in memory M5

a. Press the **[RCL]** button to display the content of memory M5.

5.100

Blinks

b. Tune to the frequency to be stored in M5 with the **CHANNEL** selector or **UP-DOWN** control. (E.g. 145.125 MHz)

5.125

Blinks

c. Press the **[ENTER]** button to store the frequency data in memory M5.

5.125

Lights up

d. Press the **[RCL]** button to check the content of memory M1.

5.025

e. Press the **[RCL]** button again to check the content of memory M2.

5.050

f. Press the **[RCL]** button once again to check the content of memory M3.

5.075

g. Press the **[RCL]** button once again to check the content of memory M4.

5.100

h. And finally press the **[RCL]** button a fifth time to check the content of memory M5.

5.125

(5) STORING REPEATER FUNCTIONS R1, R2, AND R3 TOGETHER WITH FREQUENCY DATA

Storing procedure is much the same as that for frequencies.

a. Press the **[RCL]** button to recall the content of M1. (This will display the M1 content with the dot blinking.)

b. Tune to the desired frequency (the frequency will be displayed with the dot blinking).

c. Press the **[RPT]** button to select R1, R2, or R3 (the memory content will be displayed with the dot blinking).

d. Press the **[ENTER]** button. This will store the selected repeater function in memory M1 together with the preset frequency (the memory content will be displayed with dot lit up).

e. Press the **[RCL]** button to check the repeater function and frequency data stored in memory M1 (the memory content will be displayed with the dot lit up).

Other repeater functions can be stored in memories M2 through M5 in the same way as described above.

(6) HOW TO CHANGE STORED FREQUENCIES

Frequencies stored in the memory can be easily replaced with other frequencies as described in the following example:

E.g. Changing the frequency stored in M2:

(This example shows a case where frequency data of 145.050 MHz stored in M2 is replaced with 145.150 MHz.)

a. Press the **[RCL]** button twice to recall the content of memory M2 on the display. (When 145.050 MHz is stored:)

5.050

Lit up

b. Tune to the desired replacement frequency with the **CHANNEL** selector or **UP-DOWN** control. (E.g. 145.150 MHz)

5.150

Blinks

c. Press the **[ENTER]** button. This will replace the old frequency data in M2 with the new data of 145.150 MHz.

5.150

Lights up

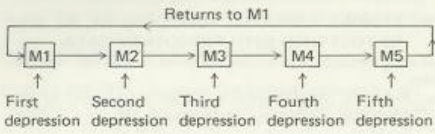
d. Press the **[RCL]** button twice to check that the new data is actually stored in memory M2.

5.150

Lit up

(7) HOW TO RECALL STORED FREQUENCIES

- a. Pressing the **[RCL]** button once to recall the content of memory **M1** on the readout. The number of times the **[RCL]** button is pressed corresponds to the number of the memory you wish to recall.



The sixth depression of the **[RCL]** button returns the recall sequence to **M1**.

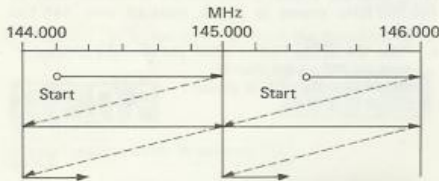
The recall operation takes higher priority over **CHANNEL** selector and scanning operation.

- b. However, when the **[CALL]** key is depressed and **[145.50c]** or **[145.55c]** is displayed, the **[RCL]** function is ineffective. Press the **[CCL]** button to clear the **[CALL]** state and restore the **[RCL]** function.
- c. When memory content is recalled on the display by **[RCL]** operation, press the **[CCL]** button to clear the **[RCL]** function and bring back the data displayed before the **[RCL]** button was depressed.

(8) FREQUENCY SCANNING

A. How to scan the entire frequency band:
The channel frequency scanning modes include entire frequency band scanning and memory frequency scanning. There are three scan stop modes.

- a. Scanning the entire 144 MHz or 145 MHz band:
Pressing the **[ALL]** button starts entire frequency band scanning. The frequency is scanned upward from an arbitrary starting frequency as illustrated below.



During scanning, this dot blinks at an interval of approx. 1 sec.

Scanning period

Channel	25 kHz step (1 MHz)	5 kHz step (1 MHz)
Switch position	40 channel	200 channel
Fast Scan	Approx. 10 sec.	Approx. 50 sec.
Slow Scan	Approx. 1 min. 20 sec.	Approx. 6 min. 40 sec.

- b. To search for busy channels:
 - Set the **MODE** switch on the front panel of the unit to the **BUSY** position.
 - Adjust the **SQUELCH** control to eliminate FM noise.
 - Scanning is stopped at the frequency at which a signal is present.



- Scanning is automatically restarted when the input signal disappears from what channel.



Blinks also when scanning is stopped

The above condition indicates that scanning is about to restart because there is no longer a signal on the channel.

- If the **PTT** button on the microphone is depressed once to put the transceiver into the transmission mode, scanning is not restarted when the found signal disappears.



Stops blinking

- c. To search for vacant channels:
 - Set the **MODE** selector on the front panel of the unit to the **VACANT** position.
 - Adjust the **SQUELCH** control to eliminate FM noise.
 - Scanning is automatically stopped at a frequency on which there is no signal.
 - Scanning is restarted when a signal appears on the previously vacant channel.



Blinks also when scanning is stopped

The above condition indicates that scanning is about to be restarted because a signal has appeared on that channel.

- If the **PTT** button on the microphone is depressed to put the transceiver into the transmission mode, scanning is not restarted even if a signal is present on the channel.



Stops blinking

- d. To scan continuously:
 - Set the **SCAN MODE** switch to the **FREE** position.
 - Adjust the **SQUELCH** control to eliminate FM interstation noise.
 - Scanning will be started at an interval of 0.25 or 2.0 seconds regardless of the presence or absence of signals.
- e. To suspend scanning operation:
 - Press the **[CCL]** button on the front panel of the unit.
 - Or press the **PTT** button on the microphone once to put the transceiver into the transmission mode.

B. How to scan the five frequencies stored in the memory:

- a. Press the **[MEMO]** button on the front panel of the unit. This will start scanning of frequencies sequentially the one stored in **M1** through to the one stored in **M5**.

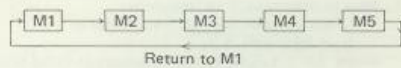


Blinks during scanning

Memory scan indicator: lights during scanning

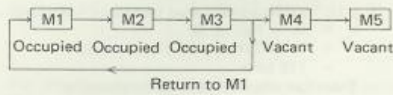
* When frequency data are stored in all the five memories:

Scan



* When M4 and M5 are vacant:

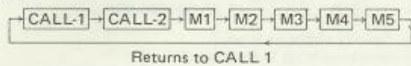
Scan



b. How to scan CALL frequencies together with memory frequencies:

Press the [CALL] button then the [MEMO] button. When all the memories are occupied, the scanning sequence is as shown in the following figure:

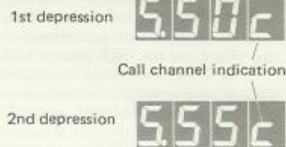
Scan



c. To search for a busy memory channel, or vacant memory channel, or perform continuous memory channel scanning, select the corresponding positions of the SCAN MODE switch on the front panel of the unit in the same way as for entire frequency band scanning.

(9) SELECTING CALL FREQUENCIES (145.50 MHz or 145.55 MHz)

a. A single depression of the [CALL] button selects call frequency 145.50 MHz, the one with the highest priority. Another depression of this button selects the other call frequency of 145.55 MHz. A third depression of the [CALL] button selects 145.50 MHz. Whenever the [CALL] button is depressed to select a call frequency, the call indication [c] is displayed after the frequency.



b. When a call channel is selected, all other key operations are ineffective except for the [MEMO] key or when the [CCL] key is depressed to reset the call function. When the call function is reset by depressing the [CCL] key, the channel frequency returns to the one displayed immediately before the [CALL] button was depressed.

When the [MEMO] key is depressed while a call channel is selected, memory and call frequencies are sequentially scanned in accordance with the selected position of the SCAN MODE switch.

(10) OTHER USEFUL OPERATIONS

a. By using the [CALL] and [CCL] keys, the two call channels and one other channel can be easily obtained. (E.g.): When a frequency of 145.525 MHz is selected with the CHANNEL selector or UP-DOWN control:

5.525 → Press the [CALL] key. →

5.50c → Press the [CCL] key. →

5.525 → Press the [CALL] key. →

5.50c → Press the [CALL] key. →

5.55c → Press the [CCL] key. →

5.525

b. By using the [RCL] and [CCL] keys, the frequency stored in memory M1 and another frequency can be easily obtained.

(E.g.): When the frequency 145.025 MHz is stored in M1 and another frequency (145.525 MHz) is selected with the CHANNEL selector or UP-DOWN control:

5.525 → Press the [RCL] key. →

5.025 → Press the [CCL] key. →

5.525

c. During [ALL] or [MEMO] scanning, pressing the PTT (Press-To-Talk) switch on the microphone suspends scanning. By utilizing this feature, scanning can be stopped just by momentarily pressing the PTT switch on the microphone when the desired frequency is reached or desired QSO station is found while scanning.

d. Step by step channel scanning can be made with the UP-DOWN control on the hand microphone.

5.3 RECEPTION PROCEDURE

- Pressing the PUSH ON/VOL switch (3) on the front panel of the unit turns the power to the unit ON. When the memory is not backed up, the initial channel selection is always started at 145.00 MHz.
- Adjust the VOL control (3) to a comfortable loudness level.
- Set the SENS control (1) to a position which best suits object signal strength.
- Adjust the SQL control (2) so that FM white noise disappears when there is no input signal received.
- Select the desired frequency as follows:
 - Select with the CHANNEL selector (5) on the front panel.
 - Select with the UP-DOWN control (29) on the microphone.
 - Press the CALL button to call on either 145.50 MHz or 145.55 MHz.
 - Press the SCAN ALL button to scan all frequencies. At this time, the following functions are available with SCAN MODE switch operation:
 - * BUSY: stops scanning at a busy channel.
 - * VACANT: stops scanning at a vacant channel.
 - * FREE: scans all frequencies to check band condi-

- tion. Two scanning speeds are selectable with the **SCAN SPEED** switch (15) on the front panel of the unit. Also, scanning interval of either 5 kHz or 25 kHz is selectable with the **SCAN STEP** switch on the rear of the unit.
- e. Press the **SCAN MEMO** button (12) to scan the frequencies stored in the memories. At this time, the following functions are available with **SCAN MODE** selector operation:
 - * Same as those obtained in **SCAN ALL** mode (with **SCAN MODE** and **SCAN SPEED** selector functions).
 - f. Press the **MEMO RCL** button (8) to recall frequencies stored in the memories.

For details of the above procedure, refer back to section 2) "Microcomputer Operation".

6. The receiver section of the C8800 is designed for such ultra-high sensitivity that the reception in the DX position can be affected by intermodulation. To obtain maximum reception performance from your transceiver, select the optimum sensitivity with the **SENS** control from among the following three positions:
 - DX:** for DX communication
 - NOR:** for normal communication
 - LOC:** for situations where reception is affected by severe interference.

5.4 TRANSMISSION PROCEDURE

1. Prior to transmission, make sure that your transmission frequency does not interfere with other communications.
2. Select transmission power of **LOW** or **HI** with the **PWR** selector (4) on the front panel of the unit. For local communication, **LOW** is recommended.
3. Press the **PTT** (30) button on the Hand Microphone to put the transceiver into the transmission mode. Talk into the microphone from a distance of 5 to 10 cm.

5.5 DETERMINING X'TAL FREQUENCY FOR REPEATER-3

1. How to determine X'tal frequency:

The basic equation for PLL frequencies is:

$$f_c = \text{freq} \times N + f_L$$

where f_c : Lowest carrier frequency (144.00 MHz)
 freq : Reference frequency (5 kHz)
 N : Minimum number of Programmable Divider (1200)
 f_L : PLL local frequency

(E.g. 1): To shift transmission frequency 1 MHz higher:

$$f_L = f_c - \text{freq} \times N$$

$$= 145.00 \text{ MHz} - 5 \text{ kHz} \times 1200$$

$$= 139 \text{ MHz}$$

Therefore, the desired X'tal frequency is:

$$\frac{f_L}{3} = \frac{139 \text{ MHz}}{3} = 46.333333 \text{ MHz}$$

(E.g. 2): To shift transmission frequency 1 MHz lower:

$$f_L = 143.00 \text{ MHz} - 5 \text{ kHz} \times 1200$$

$$= 137 \text{ MHz}$$

Therefore, the desired X'tal frequency is

$$\frac{f_L}{3} = \frac{137 \text{ MHz}}{3} = 45.666666 \text{ MHz}$$

2. Specifications of X'tals

Overtone X'tal Type 25U

For frequency deviations, see the following table.

Temperature	Frequency deviation
25°C	±20 PPM
-10°C ~ +50°C	±10 PPM

3. X'tal installation and adjustment

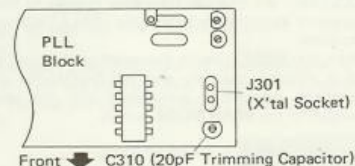
- a. With the front panel of the unit facing forward, remove the top lid.
- b. Now you will see a shielded box, which contains the PLL block, at the front of the unit. Remove the lid from the box.
- c. The socket (J301) to accommodate the X'tal for Repeater-3 is located to the right of the PLL shielded box (see the following figure). Install the X'tal of the desired frequency into this socket (J301).
- d. Next, adjust the frequency.

A frequency counter capable of covering the transmission frequency band (140 MHz band) is required for frequency adjustment.

First, set the **PWR** selector on the front of the unit to **LOW**, then make the necessary connections to allow transmission frequency counting.

Using the **CHANNEL** selector or **UP-DOWN** control, set the channel frequency to 145.00 MHz, then press the **[RPT]** key to select Repeater-3.

Put the transceiver into the transmission mode, and adjust the trimming capacitor (C310: 20 pF) so that the desired frequency shift is obtained in the frequency counter readout (E.g. The counter readout will be 146.00 MHz for upward shift of 1 MHz.)



NOTE:

When the transceiver is operated in the Repeater-3 mode, the transmission frequency is not displayed on the frequency readout. Exercise the utmost care at such times to avoid straying out of the amateur band.

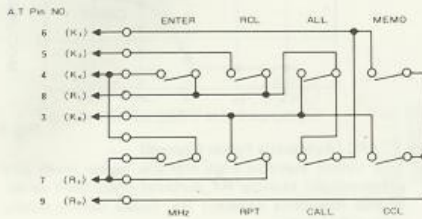
5.6 ACCESSORY TERMINALS

1. The pin configuration of the accessory terminal on the rear of the unit is as follows:



1	GND	
2	EXT BACK UP	
3	K8	For Key Board
4	K4	
5	K2	
6	K1	
7	R2	
8	R1	
9	R0	

2. For remote control keyboard, use the following circuit configuration:



5.7 ADJUSTING PIEZO-ELECTRIC BUZZER SOUND LEVEL

The piezo-electric buzzer is fixed on the bottom cover (speaker side). The sound adjustment variable resistor is located adjacent to the piezo-electric buzzer connector. Remove four screws from the bottom cover, lift the cover, then adjust the sound level using a slot driver.

5.8 RESETTING THE MICROCOMPUTER

In the event of a malfunction, or when key operation is not effective, reset the microcomputer in the following way:

1. Turn the unit power switch and back-up switch located at the rear side, OFF. (The battery and power supply may be kept connected.)
2. After about 5 seconds, turn the power switch and the back-up switch, ON.

SERVICE MANUAL SECTION

6. FUNCTIONS

6.1 RECEIVER SECTION

- * The receiver is a double conversion super-heterodyne device with the 1st IF at 10.7 MHz and the 2nd IF at 455 kHz.
- * Incoming signals to the antenna terminals (J802) pass through an antenna switching circuit within the transmission booster (PB01) to JR01 of the RF pre amp (PR01).
- * RF pre amp. outputs are MOS FET amplified in the RF main amp. (QR01).
- * Sensitivity adjustments
 1. DX position: Employs 2-stage RF amplification, RF pre amp. (QQ01) and RF main amp. (QR01).
 2. NOR-LOC position: By means of 2 PIN diode switches (QQ02 and QQ03), RF pre amp. (QQ01) is deactivated and only RF main amp. functions.
 3. Sensitivity for each position is preset by application of positive voltages to the FET gate 1 of the RF main amp. (QR01).
- * QR01 outputs pass through a 3-stage helical cavity and are fed to gate 1 of 1st mixer QR04 (MOS-FET). Local signals from PLL (PL01), board J125-1, are fed through LR02 to gate 2. (Local signals: 133.3~135.3 MHz)
- * Signals converted to 10.7 MHz by QR04 pass through monolithic crystal filters (FR01 and FR05) thereby improving the set selectivity, intermodulation suppression, etc.
- * Signals that have passed through the crystal filters are amplified by 1st IF amp. (QR05), and fed to 2nd mixer (QR06).
- * QR07 is the 2nd local oscillator.
- * 10.7 MHz fed to QR06 is converted for 2nd IF, 455 kHz, and is fed to ceramic filters (FR03 and FR04).
- * Signals from the ceramic filters are amplified by QR09 and QR10, and then ratio detected. Detection outputs pass through the de-emphasis circuit, and are amplified by AF pre amp. (QR13).
- * Signals amplified by QR13 and QR20 drive speakers.
- * The squelch circuit amplifies QR10 outputs (noises). Its outputs, pass through a L-C filter circuit and amplified by a 2-stage noise amplifier comprising QR15 and QR16. These signals are then diode rectified to provide DC voltages.
- * Diode rectified DC voltages are fed to the base of QR19.
- * The QR19 collector is connected to the base of QR13 AF amp., to provide squelching functions. Also QR13 base currents are used to switch QR14 to provide scan control signals.

6.2 TRANSMITTER SECTION

- * Signals from external microphones (MP716) amplified by Q401 and Q402, are rolled off above 3 kHz by a roll-off filter, and fed to C172 of the VCO circuit, to direct frequency modulate the VCO by reactance modulation.
- * PLL board outputs are supplied to #2 pin of JT01 of the transmitter younger stage board (PT01).
- * Signals supplied from the PLL board are amplified sequentially by QT01, QT02, QT03, and QT04, and via #1 pin of JT02 fed to #1 pin of JB01 of the TX booster (PB01).
- * QT01 and QT02 operate under a 9 V line voltage, but +B of QT03 and QT04 are regulated by the APC circuit (JT02 #3 pin).
- * Signals fed to #1 pin of JB01 are power amplified by QB01 to approximately 20 W.

- * Signals amplified by QB01 pass through a 3-stage low bandpass filter to the antenna terminals.
- * QB01 is regulated by the +B line voltage of the APC circuit, so that the high & low power outputs can be trimmer adjusted within the PC01 board.

[C8800 MODULATION DISTORTION]

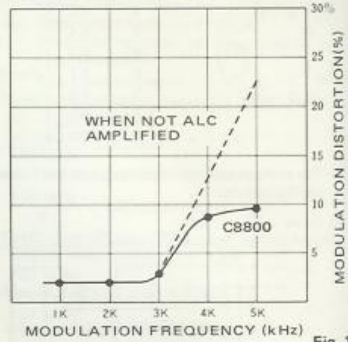


Fig. 1

6.2.1 APC (Automatic Power Control)

1. This circuit controls high and low power levels and automatically reduces RF outputs when SWR varies. It also maintains constant RF power during supply voltage fluctuations.
2. This APC board (PC01) is controlled by the DC voltage supplied by the SWR detector within booster board (PB01).
3. Progressive wave components are applied to QC03 and reflective wave components to QC04.
4. As each source for QC03 and QC04 is compulsorily biased, base voltage variations in QC03 and QC04 are more likely to be reflected on the collector side.
5. When, for instance, the supply voltage rises, or SWR deteriorates, the progressive or reflective wave level increases and reduces the QC03 and QC04 collector voltages.
6. When the QC03 and QC04 voltages are reduced, the QC02 emitter voltage decreases, and QC01 (transistor) approaches a cut off state. This causes a reduction in the Q806 emitter current.
7. Reduction in the Q806 emitter current limits the current in QT03 and QT04 in younger board (PT01) and QB01 of the booster, thereby reducing the RF power.

6.3 PLL SECTION

The PLL block used for C8800 has its PLL controlled by a 13-bit BCD code generated in the microcomputer section. In transmission mode it's outputs directly generate the frequencies required. In receiving mode, they generate frequencies 10.7 MHz below those required.

(Example) PLL circuit frequency relations in a 145.000 MHz transmission mode.

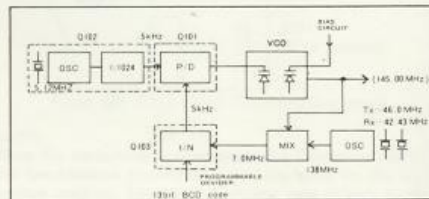


Fig. 2

6.3.1 PLL IC

This PLL IC comprises:

- * Reference frequency oscillator section (Q102) 5.12 MHz
- * Phases detector circuit P/D P/D
- * Programmable counter section 1/N

A 13-bit BCD coded command from microcomputers (QL01 and QL02) is applied, determining the count down ratio. Frequencies from the mixer are divided by this ratio, and applied to the phase detector circuit.

(1) Programmable counter section (Q103)

A 13-bit BCD coded command from the microcomputer (QL02) is applied, determining the count down ratio. Frequencies from the mixer are divided by the ratio, and applied to the phase detector circuit.

DIS PLAYED FREQ. (MHz)	Q103(TC9122P) PIN NO.													COUNT DOWN RATIO (N)
	15	14	13	12	11	10	9	8	7	6	5	4	3	
144.000	1	0	0	1	0	0	0	0	0	0	0	0	0	1200
144.005	1	0	0	1	0	0	0	0	0	0	0	0	1	1201
144.010	1	0	0	1	0	0	0	0	0	0	0	0	1	1202
144.015	1	0	0	1	0	0	0	0	0	0	0	1	1	1203
144.020	1	0	0	1	0	0	0	0	0	0	0	0	0	1204
...
144.100	1	0	0	1	0	0	0	1	0	0	0	0	0	1220
...
144.500	1	0	0	1	1	0	0	0	0	0	0	0	0	1300
...
145.000	1	0	1	0	0	0	0	0	0	0	0	0	0	1400
...
145.240	1	0	1	0	0	0	1	0	0	1	0	0	0	1448
...
145.500	1	0	1	0	1	0	0	0	0	0	0	0	0	1500
...
145.995	1	0	1	0	1	1	0	0	1	1	0	0	1	1599
N	1	5	9	9										

Count down ratio (N) computation formula:

$$(\text{Desired frequency in kHz} - 138,000 \text{ kHz}) \div 5 = \text{count down ratio}$$

(Example) If 145,000 MHz is desired:
 $(145,000 - 138,000) \div 5 = 7,000$
 $7,000 \div 5 = 1,400$
 (counter down ratio)

(2) Phase detector circuit (P/D cct.) (Q101)

- 1) Detects phase differences between 5 kHz which is 1/1,024 of the reference oscillator frequency (5.12 MHz), and the frequencies from programmable counter.
- 2) This circuit varies VCO circuits oscillating frequencies by obtaining detected signals from #3 pin, and converting them to DC voltages through an integrating circuit comprising C's and R's, and varying the voltages applied to varicaps (varactors).

6.3.2 VCO circuit (P150)

- (1) Outputs from P/D cct. of Q101 PLL IC are converted to DC voltages via an integrating circuit comprising C's and R's.
- (2) Variations in these DC voltages are fed to the Q151 varicap diodes, to alter varicap capacitances.
- (3) By capacitance variations in varicap diodes, the VCO circuit oscillating frequencies are controlled.
- (4) Depending on DC voltage variations, a maximum frequency variation of approximately 14 MHz can be

provided.

6.3.3 Local oscillator section (local OSC)

- (1) The local OSC section provides by overtone oscillation 127.3 MHz for RX and 138.0 MHz for TX.
- (2) This signal is applied to the mixer section of Q202.

6.3.4 Mixer section (Mix, Q201 and Q202)

- (1) Signals from VCO are picked up after passing through Q120 and Q121, and applied to the mixer section through Q201 the buffer amp.
- (2) In the mixer section, signals from VCO and local OSC are mixed, providing signals of 6.0 to 7.995 MHz.
 $F(V_{CO}) - F(\text{local}) = 6.0 \sim 7.995 \text{ MHz}$
- (3) Signals from the mixer section, after passing through LPF, are amplified by Q203 and Q204 and applied to the 1/N circuit of PLL IC (Q103).
- (4) PLL IC Unlock
 Extracts lock and unlock signals from phase detector circuit.

6.3.5 Unlock switch circuit (UL, Q104)

Depending on PLL IC and UL output conditions, UL and lock modes are judged by Q104.

- (1) Signals to be applied to 1/N circuit are frequency divided at a predetermined count down ratio, and signals thus divided are fed to the phase detector circuit via the 1/N circuit.
- (2) Until reference signals and 1/N circuit signals coincide within the phase detector circuit, repeated controls are exercised within the Fig. 2 loop.
- (3) When reference and 1/N circuit signals coincide, it is called a locked state.

6.4 CONTROLLER SECTION

Consists of the following sections:

- PL01: Microcomputer section
- PD01: Display section
- PD01: Channel selector section (manual)
- PM01: Control I/O decoder section

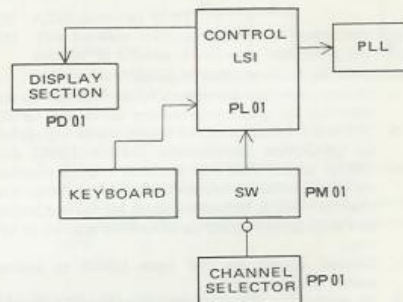


Fig. 3

* Re control LSIs QL01, and QL02
 These MOS LSIs function with a power supply in a range of +8V to +10V. It is 9V in C8800.

6.4.1 To control external circuits, the following outputs are provided:

- (1) PLL IC programmable counter drive
 13-bit BCD coded outputs for driving programmable counter are provided at pins #7 ~ 18 of QL02 and #2 pin of QL01, a total of 13 terminals.
- (2) 7-segment LED drive
 Signals from pins #10 ~ 17 and #20 ~ 24 of QL01 drive a 4-digit 7-segment LED.

- (3) Feature section for repeater mode selection
By punching RPT on keyboard, outputs as per Fig. 4 are provided at pins #19(A7), #20(B7), #21(C7), and #22(D7).

	A7	B7	C7	D7
S	1	0	0	0
R1	0	1	0	0
R2	0	0	1	0
R3	0	0	0	1

Fig. 4

6.4.2 To operate LSIs, the following commands are applied to terminals indicated:

- (1) Initial clear (INIT, pin #9)
When turning power on, a positive pulse is applied to pin #9 to clear all in LSIs.
- (2) Matrix circuit (pins #21 (R0) ~ #24 (R3) and #5 (K1) ~ #8 (K8))
By using this matrix circuit, 16 key inputs are feasible.

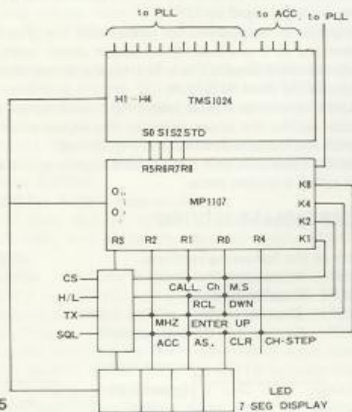


Fig. 5

- * Selection by channel knob (manual)
 - a. Channel selection commands to microcomputer are delivered by photo-interruptors QP01 and QP02.
 - b. The two photointerruptor signals are so segregated by UP-DOWN discriminator circuits (QM03 and QM04) within PM01 as to divide channel number variations into UP key and DOWN key. When the channel knob is turned an equal number of pulses to the channel number variations are applied to UP key.
 - c. Divided signals are fed from QM05 to analog switch QL06 via JM04.
 - d. By applying a high level voltage to the #13 control terminal of QL06 for UP and #12 for DOWN, terminals R0 and K4 for UP, and R0 and K2 for DOWN, are short circuited through a resistance of approximately 260 ohms in value.
 - e. In short, by segregating into UP and DOWN, the analog switch in QL06 is turned on, closing the matrix.
- * Selection by microphone switch
 - a. In UP-DOWN control by rotary switch, the analog switch is turned on and off by pulse.
 - b. In UP-DOWN control by microphone switch, the analog switch is turned on and off by DC.
 - c. UP-DOWN commands from microphone are applied to #5 and #6 of QL06.

[CHANNEL SELECTOR STRUCTURAL DIAGRAM]



Fig. 6

- 1) Channel selection
Matrix circuits are closed between R0 and K2 for UP, and between R0 and K2 for DOWN.
- 2) Memory enter (MEMO-ENTER)
Matrix circuit between R1 and K4 is closed. Its function is to memorize the frequency being displayed.
- 3) Memory recall (MEMO-RCL)
Matrix circuit between R1 and K2 is closed. Its function is to recall the frequency in memory.
- 4) Scan all (SCAN-ALL)
Matrix circuit between R1 and K8 is closed. Its function is to have scanning started from the channel displayed in the UP direction.
- 5) Scan memory (SCAN-MEMO)
Matrix circuit between R1 and K1 is closed. Its function is to have the 5 channels in memory sequentially scanned.
- 6) Repeater (RPT)
Matrix circuit between R2 and K8 is closed. Its function is to change A7 - D7 codes from S to R1 to R2 to R3 to S, in this sequence.
- 7) Call channel (CALL CH)
Matrix circuit between R1 and K1 is closed. Its function is:
to call 145,50 at the initial switch on
to call 145,55 at the second switch on
to call 145,50 at the third switch on
and to repeat this process.
- 8) CCL
Matrix circuit between R0 and K8 is closed. Its function is to cancel all of MEMO RCL, SCAN ALL, SCAN MEMO, and CALL CH.
- 9) MHz
Matrix circuit between R2 and K4 is closed. Its function is to change just MHz order numerals.
Example: 145,025 to 144,025 to 145,025
- 10) Scan speed selection
 - a. Matrix circuit between R3 and K2 is closed.
 - b. By scan speed switch (SM02) on front panel, the analog switch of QL07 is turned on or off.
 - c. When the analog switch is on, the scan speed is low: 0.5 channels per second.
 - d. When the analog switch is off, the scan speed is high: 4 channels per second.
- 11) Scan mode selection (Busy, Auto, Vacant)
 - a. In busy position, scanning stops when a signal is received.
 - b. When a signal is received, low level is output from the QR14 collector.
 - c. Low level from QR14 collector is applied to QM02 which inverts it and provides high level output.
 - d. Output from QM02 is applied to the analog switch QL07 and QL07 closes the matrix circuit between R3 and K8.
 - e. In vacant position, scanning ceases when no signal is received.

- f. For no signal, high level output is provided on QR14 collector.
 - g. High level signals from the QR14 collector are applied to QM02, cycled twice, to provide high level output.
 - h. Output from QM02 is applied to analog switch QL07 and closes the matrix circuit between R3 and K8.
- 12) Re: control section in transmission mode
 - a. While transmitting the matrix circuit between R3 and K4 should be closed, nullifying all inputs, to insure no IC environmental variation.
 - b. Analog switch QL07 is turned on and off by transmission at +B.
 - 13) Re: selection between 5 kHz and 25 kHz
 - a. Rear panel slide switch S803 selects:
 - S803 off = 5 kHz separation
 - S803 on = 25 kHz separation
 - b. Matrix circuit between O7 and K1 is closed.
 - 14) Chip select switch (CS)
 - a. Matrix circuit between R3 and K1 is closed.
 - b. The chip select switch is ganged with the power switch.
 - c. Switching to +B turns analog switch QL107 on.
 - Analog switch on: Normal operation
 - Analog switch off: Stops controller functions and turns display off. However, the memory section continues to function.

[5.50C FIRING PRINCIPLE]

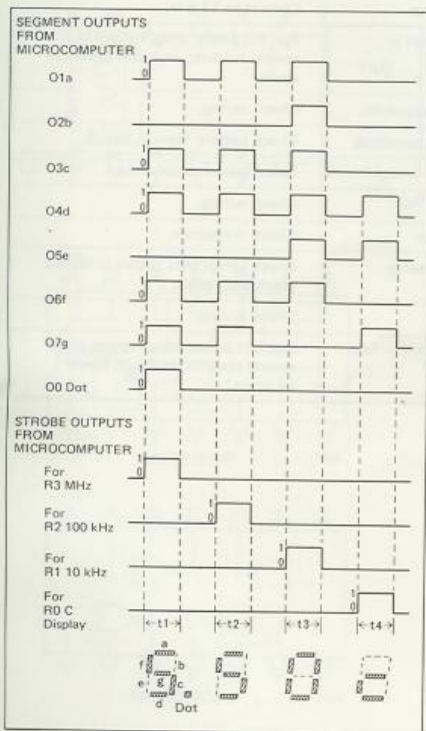


Fig.7

6.4.3 Display section

- * LSI QL01 segment outputs are driven by segment drive IC's QL04 and QL05, and QL03 dynamically drives a 4-digit 7-segment LED.
- * Levels when 145.50C is displayed are shown in Fig. 7.
- * Per the above, Fig. 7 signals are repeatedly applied to O0-O7 terminals, firing each segment.
- * In synchronization with QL01 segment outputs, strobe signals from R0—R3 are applied to QL02 (digit driver).
- * QL02 displays 4 digits QD01-QD04.
- * Close scrutiny of a dynamic drive reveals that digits are sequentially lit up, one digit at a time. However, due to fast cycles, all 4 digits appear to light up simultaneously.

6.4.4 Operation of CTN-5

The 1750 Hz tone signal is fed to Q101 emitter during transmission. This signal passes through the MIC input circuit and AF circuit, and is then fed to the modulator where it is modulated. The modulation degree can be adjusted with the output level control VR on CTN-5. In CW mode, Q101 is reverse biased, so the signal is not modulated.

6.4.5 Back-up unit

- (1) With QZ04 (zener) as reference voltage, lowering of the base and emitter voltages in QZ01 turns QZ01 on.
- (2) QZ01 is used to turn on QZ02, and QZ02, QZ03, thereby driving the DC-DC converter (AZ01).

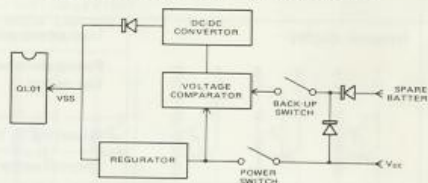


Fig. 8

- (3) AZ01 provides 10 V.
- (4) This back-up unit operates when the power supply voltage is around 11 V, and maintains the power supply for MEMO circuits of QL01 at 9 V until it is reduced to 3 V.

6.4.6 Controller peripheral circuits and functions

- (1) QL03 (μ PA47C) digit driver
 - * Digits are lit up and switched by strobe signals (R0—R3) from QL01, and controller IC.
 - * μ PA57C is an integrated circuits of darlington connected NPN transistors and peripheral resistors.

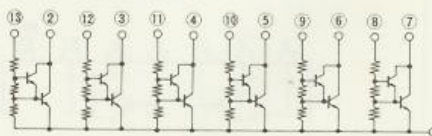


Fig. 9

- (2) QL04 and QL05 (TA-76) segment drivers
These are ICs for driving LEDs.

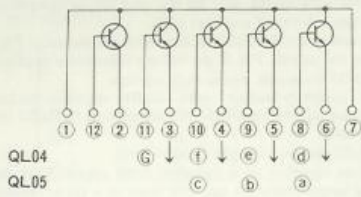


Fig. 10

- (3) QL07 (14016CP)

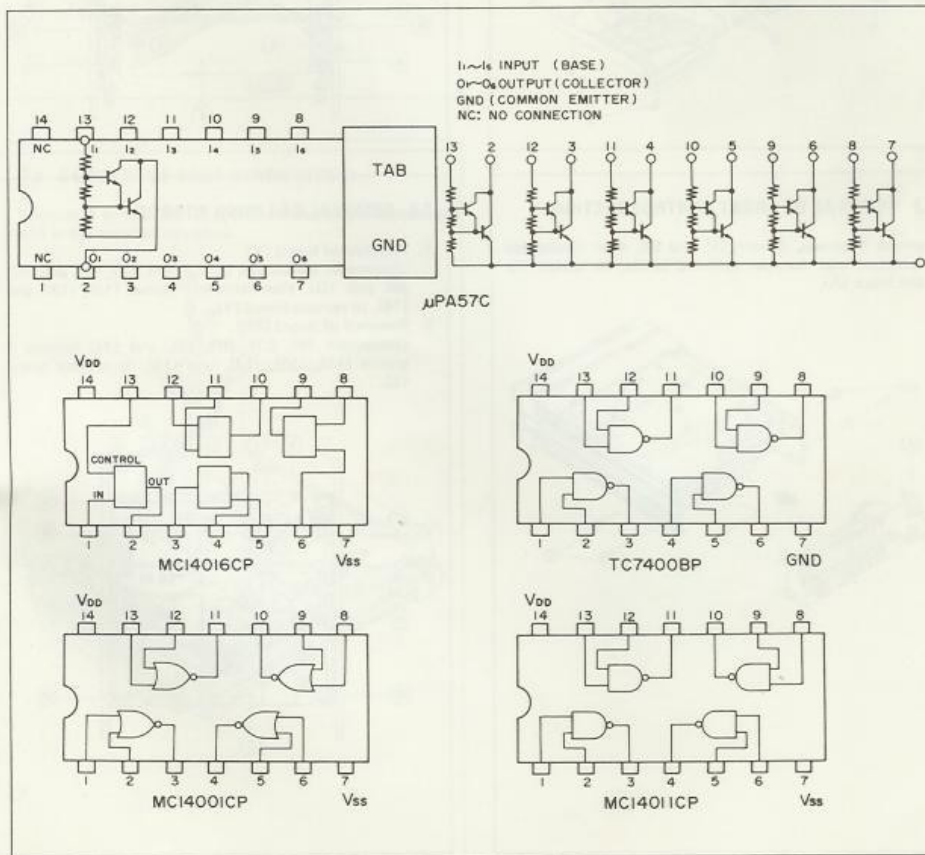
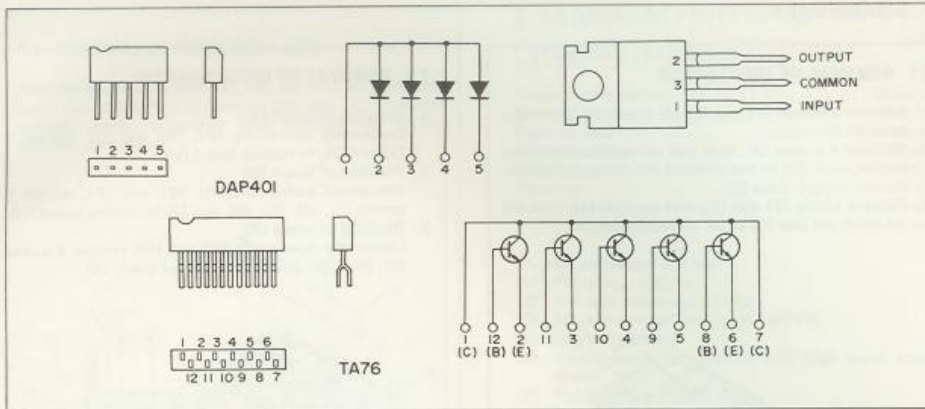
- This IC is for analog switches, and in C8800 is used in QL06, QL07, QM01, and QM02.
- As shown below, when a high level signal is applied to CONTROL, IN and OUT turn on.



Fig. 11

6.4.7 Trouble shooting

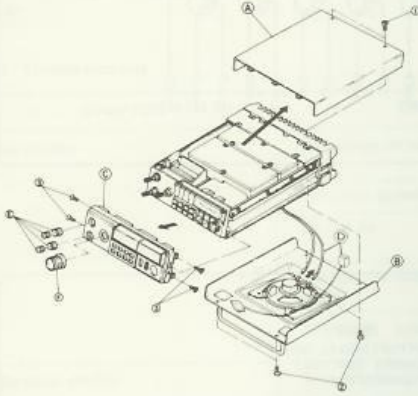
SYMPTOM	CAUSE	REMEDY
No display	No voltage on each B line.	Check power supply circuit board and connector contacts.
	LSI clock generator not oscillating.	Check circuit parameters
	CS not on.	Check power supply circuit board and connector contacts.
	No signal at output terminals to LED.	No voltage at +B for segment driver.
	Miswiring.	Check wiring, or poor connector contacts.
Irregular display	Low power supply voltage.	Correct to 13.8 V.
	Power switched on and off in fast cycles.	Pull out power plug, replace after several seconds, and turn power on again.
	Miswiring to individual segments.	Check wiring.
	Shorted pattern at LED terminals.	Check pattern (circuit board).
Punching keys do not provide proper functions	TX SW is on.	Check power supply block.
	Keyboard miswiring.	Check wiring.
	Connector poor contacts.	Check connector.
Channel display remains UP-DOWN and other keys do not work.	UP-DOWN has turned analog switch on.	Check UP-DOWN circuit in feature block and repair.
Display outside of band or wrong CH STEPS.	Miswiring.	Check wiring.
	Power switched on and off in fast cycles.	Pull out power plug, replace after several seconds, and turn power on again.



7. DISASSEMBLY

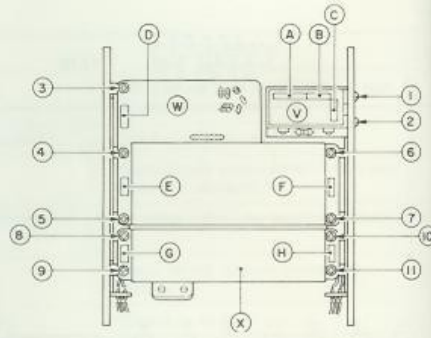
7.1 REMOVAL OF ESCUTCHEON

1. Remove 2 screws (1) and lift off top cover (A) in the arrowed direction.
2. Remove 4 screws (2), then pull off speaker jacks and buzzer cord (D) in the arrowed direction, for loosening the bottom cover (B).
3. Remove knobs (E) and (F), and 4 screws (3), then lift off the front case (C) in the arrowed direction.



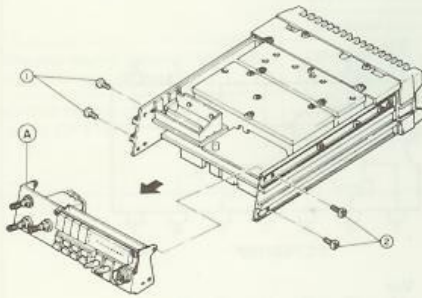
7.3 REMOVAL OF UPPER BOARDS

1. Removal of board (V)
Disconnect connectors (A), (B), and (C), remove 2 screws (1) and (2), to remove board (V).
2. Removal of board (W)
Disconnect connectors (D), (E), and (F), remove 5 screws (3), (4), (5), (6), and (7) to remove board (W).
3. Removal of board (X)
Disconnect connectors (G) and (H), remove 4 screws (8), (9), (10), and (11) to remove board (X).



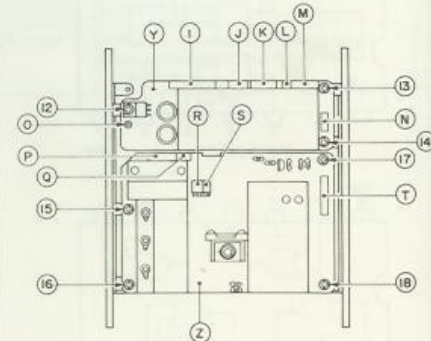
7.2 REMOVAL OF FRONT CONTROL SECTION

Remove 8 screws, 4 each (1) and (2), then disconnect connectors and desolder soldered joints, to loosen the front block (A).



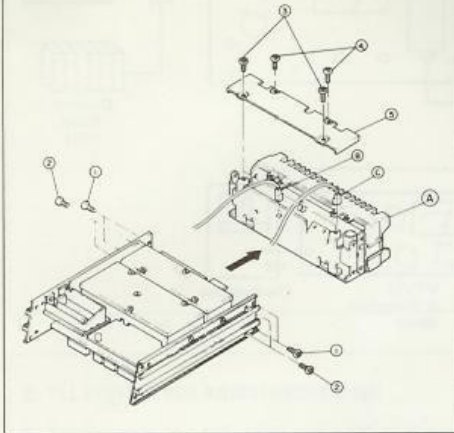
7.4 REMOVAL OF LOWER BOARDS

1. Removal of board (Y)
Disconnect connectors (I), (J), (K), (L), (M), and (N), pin jack (O), then remove 3 screws (12), (13), and (14), to remove board (Y).
2. Removal of board (Z)
Disconnect (P), (Q), (R), (S), and (T), remove 4 screws (15), (16), (17), and (18), to remove board (Z).



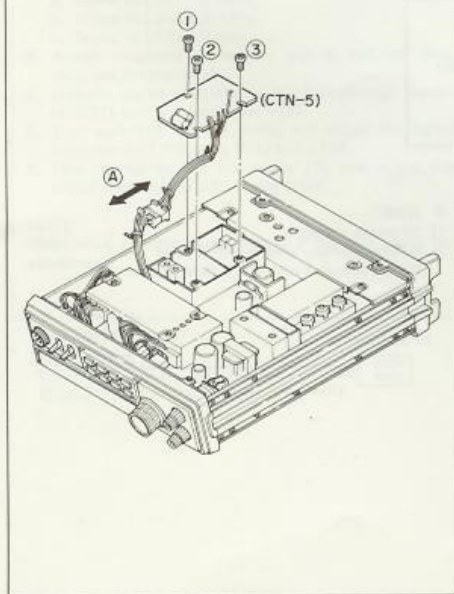
7.5 REMOVAL OF FINAL HEAT-SINK

Remove 8 screws, 2 each (1), (2), (3), and (4), shielding plate (5), disconnect connectors (B) and (C), desolder soldered joints, to remove final heat-sink (A) in the direction arrowed.



7.6 REMOVAL OF TONE BOARD (CTN-5)

Remove 3 screws (1), (2) and (3), then pull off connector (A) in the arrowed direction.



8. ADJUSTMENT PROCEDURES

STANDARD CONDITIONS

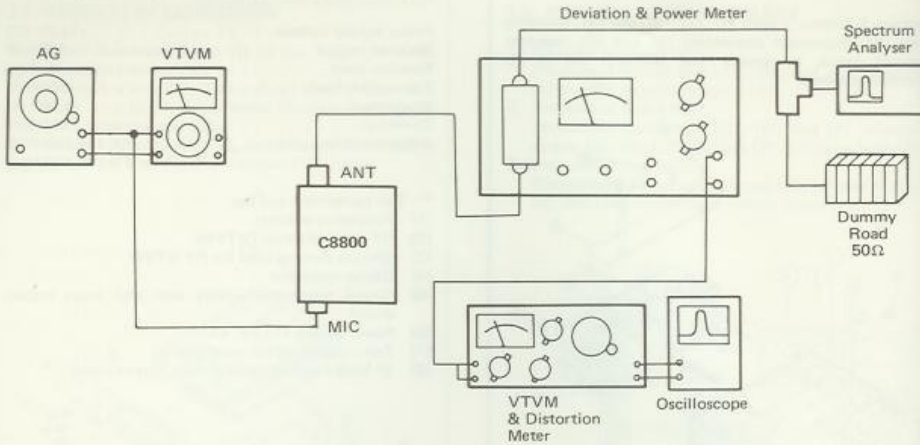
Power supply voltage	13.8V DC
Receiver output	500 mW
Receiver load	4 ohms
Transmitter load	50 ohms
Modulation	1,000 Hz
Deviation	±3.5 kHz
Adjustment frequency	RX 145.500 MHz
	TX 145.480 MHz

* Test equipment and jigs

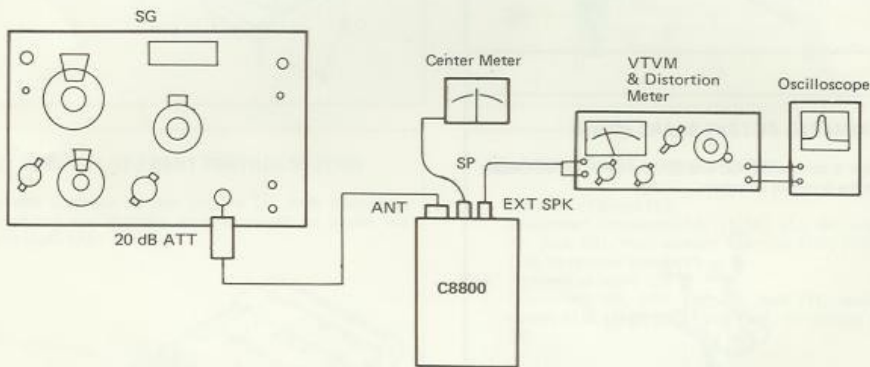
- (1) Frequency counter
- (2) RF millivoltmeter (VTVM)
- (3) 50-ohm dummy load for RF VTVM
- (4) Digital voltmeter
- (5) Circuit tester (preferably with high input impedances)
- (6) Power supply (13.8V, 4A)
- (7) Transmitting jig (or microphone)
- (8) 2P Molex socket (coaxial with N type male)

TRANSMITTING AND RECEIVING CONNECTIONS

TRANSMITTING



RECEIVING



8.1 PLL ADJUSTMENTS (P101)

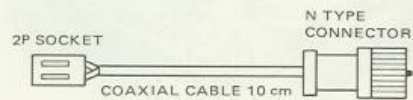
- * When adjusting PLL and RX, keep PTT off unless otherwise specified.
- * Adjust PLL before RX and TX.
- * PLL section is thoroughly factory adjusted, so that these trimmers require no further adjustment.
- * While PLL related adjustments are being carried out, leave socket J125 disconnected. Replace the socket after adjustments are completed.

ADJUSTMENT CONDITIONS

SENS.DX
SQL.	MIN
PWR.	HI
VOL.	MIN
MODE.	FREE
SCAN.	LOW
CH STEP.	25 kHz
BUCK UP.	OFF
POWER SUPPLY.	13.8 V

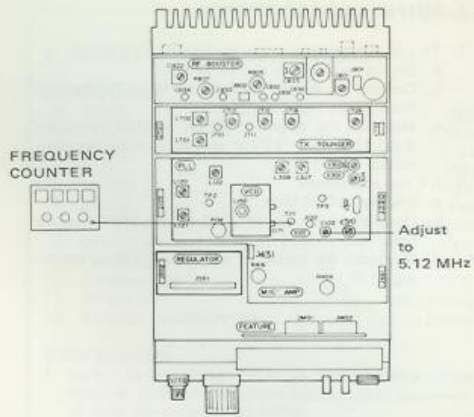
JIGS

- 1) 2P molex socket
- 2) 50-ohm dummy load for RF VTVM
N type supplied with RF VTVM is to be used.



1. PLL COMPARATOR OSCILLATOR ADJUSTMENTS

Connect frequency counter to TP1 and adjust by C103 to 5.1200 MHz \pm 100 Hz.



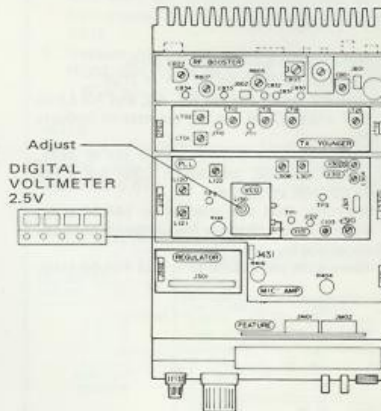
2. PLL SECTION VCO ADJUSTMENTS (P150)

1. Position cores of L307, L308, and L122 as shown below:



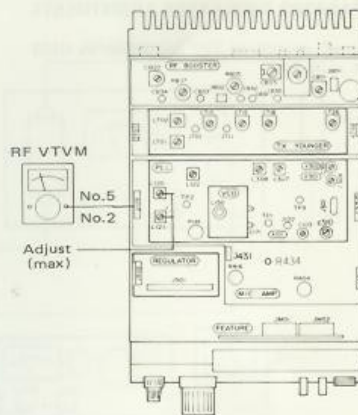
2. Adjust the above 3 coils as follows:
 - a. Screw in L307 1.5 turns.
 - b. Screw in L308 4.5 turns.
 - c. Screw in L122 1.0 turn.
3. Adjust frequency display on unit to 145,000 MHz using the channel knob.
4. Connect digital voltmeter to the feed-through capacitor C171 that is mounted on VCO.
5. Then switch to the TX mode, and adjust the digital voltmeter to 3.0 V using VCO coil L150.
6. Then switch to the RX mode (S), and adjust the digital voltmeter to 3.0 V using R136.

NOTE:
When using a circuit tester, use 10 V range or above for adjustments.



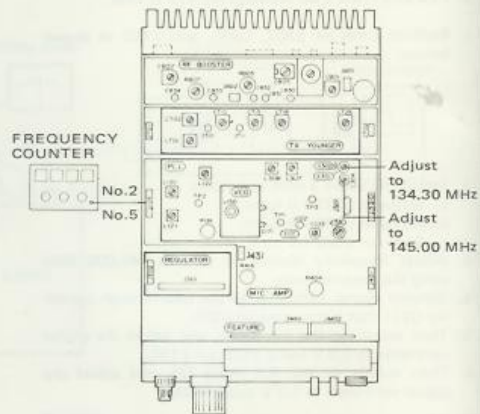
3. OUTPUT COIL ADJUSTMENTS

1. TX coil adjustment
 - a. Set the unit display at 145.50 MHz.
 - b. Connect to #5 pin of J125 an RF VTVM which has a 50-ohm load resistance.
 - c. Maximize the output at #5 pin of J125 by adjusting L120. (RF VTVM should indicate approximately 0.3 V)
2. RX coil adjustment
 - a. Display 145.50 MHz.
 - b. Connect to #2 pin of J125 an RF VTVM which has a 50-ohm load resistance.
 - c. Maximize the output at #2 pin of J125 by adjusting L121.



4. FREQUENCY ADJUSTMENTS

1. Turn channel knob to display 145.00 MHz.
2. Connect frequency counter to #2 pin of J125.
3. Switch to the RX mode (where A1, A2, and A3 LEDs are off), and adjust C304 for the counter to indicate 134.40 MHz.
4. Then connect frequency counter to #5 pin of J125.
5. Switch to the TX mode, and adjust C301 for a frequency 145.00 MHz at #5 pin.
6. Stop transmitting, shift the channel to 144.00 MHz, transmit and make sure that the frequency is indicated by the channel display.
7. Similarly make sure on 145.98 MHz and 145.50 MHz.



* The above completes PLL related adjustments, so that J125 socket can now be reconnected.

8.2 TX ADJUSTMENTS

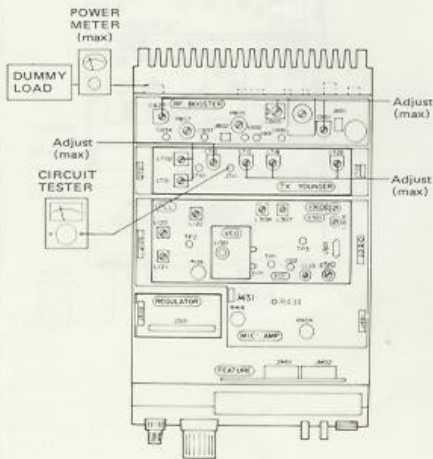
1. YOUNGER BOOSTER PWR ADJUSTMENTS

(CONDITIONS)

1. SENS. DX
2. SQL. MIN
3. PWR HI
4. VOL MIN
5. MODE FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP OFF
9. Power supply 13.8 V
10. Dummy load. 50 Ω
11. Frequency 145.48 MHz
12. External UP-DOWN SW Center

(PROCEDURES)

1. Using the channel selector knob, adjust to 145.48 MHz.
2. Turn trimming resistors RC07, RC08, and RC12, of APC board to extreme left (minimum).
3. Maximize CB22 booster board capacitance.
4. Connect a tester to JT11 of the younger board.
5. Switch to TX mode, and adjust a few times to maximize voltages at LT01, LT02, and CT10. (Should be approximately 0.26 V)
6. Disconnect the circuit tester, and while watching the RF power meter, maximize RF power by adjusting a few times CT15, CT18, and CT26 of the younger board, and then CB01, CB05 of the booster board, in that sequence. (RF power should be approximately 18 W).



2. POWER PROTECTOR ADJUSTMENTS

(CONDITIONS)

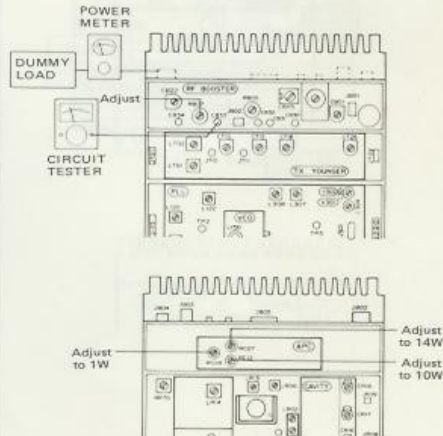
1. SENS. DX
2. SQL. MIN
3. PWR HI
4. VOL MIN
5. MODE FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP OFF
9. Power supply 13.8 V
10. Dummy load. 50 Ω
11. Frequency 145.48 MHz
12. External UP-DOWN SW Center

(PROCEDURES)

1. Switch to high power TX mode, and connect a circuit tester to CB33 of the booster board. Adjust accurately to reach the dip point by RB07.
2. Switch to low power, and set the RF power at 1 W by adjusting RC07 of the APC board.
3. Switch to high power, and set the RF power at 14 W by adjusting RC08.
4. Switch to the RX mode. Replace the ANT dummy load with the SWR-5 dummy load, and transmit at high power. By adjusting RC12, set the RF power at 10 W.
5. Replace ANT dummy load with 50 ohms, and adjust RC07 and RC08 to obtain 14 W at high power and 1 W at low power.

NOTE:

When using SWR-5 dummy load, the total length of the coaxial cable from ANT connector to the dummy load should be $0.67 \times \lambda/2 \times \eta$, or 69 cm and 1,038 cm.



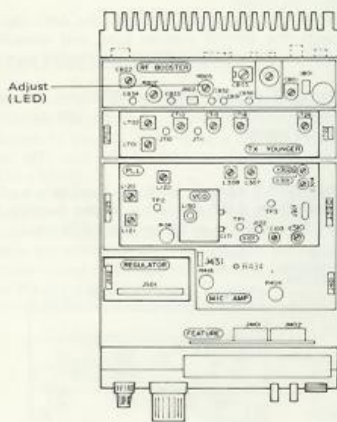
3. TX METER ADJUSTMENTS

(CONDITIONS)

1. SENS.DX
2. SQL.MIN
3. PWR.HI
4. VOL.MIN
5. MODE.FREE
6. SCAN.LOW
7. CH STEP.25 kHz
8. BUCK UP.OFF
9. Power supply13.8 V
10. Dummy load.50 Ω
11. Frequency145.48 MHz
12. External UP-DOWN SWCenter

(PROCEDURES)

1. Switch to high power TX mode, and by adjusting R805 of the booster board, set at the point where the 9th LED (the 3rd red) is turned off.
2. Switch to low power, and confirm that one of the first 4 LEDs turn on. (1st through 4th for low power, and 7th through 9th for high power is OK).



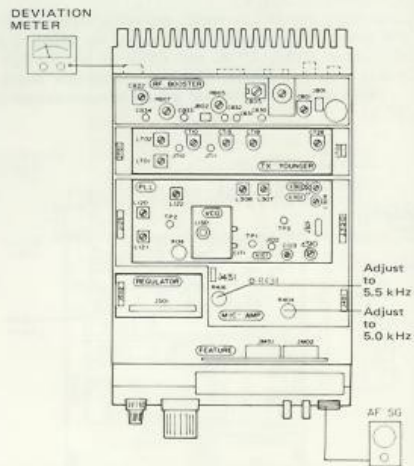
4. DEVIATION ADJUSTMENTS

(CONDITIONS)

1. SENS.DX
2. SQL.MIN
3. PWR.HI
4. VOL.MIN
5. MODE.FREE
6. SCAN.LOW
7. CH STEP.25 kHz
8. BUCK UP.OFF
9. Power source13.8 V
10. Dummy load.50 Ω
11. Frequency145.48 MHz
12. External UP-DOWN SWCenter

(PROCEDURES)

1. Apply to the MIC input terminals a signal whose output at AG is approximately 1 kHz, 30 mV RMS. Then turn R404 of the PLL board to the extreme counter-clockwise position (maximum gain).
2. Switch to the TX mode, and by means of R416, set where the deviation is 5.5 kHz maximum.
3. Using R404, set for a deviation of 5.0 kHz maximum. (At 3.5 kHz dev, MIC sensitivity = 0.7 – 4 mV as measured in an open state.)



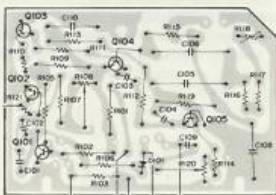
5. TONE UNIT & CTN-5 (tone oscillator for repeater drive) ADJUSTMENTS

(CONDITIONS)

1. MODE FM
2. Band 144 MHz
3. VFO 145 MHz
4. PWR MAX
5. MIC input None

(PROCEDURES)

1. Set the Push Tone Switch to ON (C8800 is set to transmit mode with signal modulated by CTN-5).
2. Turn R108 fully counterclockwise.
3. Adjust the modulation frequency to 1750 Hz by adjusting R118 on the P.W. board (the frequency counter indicates the output of the FM linear detector).
4. Adjust R120 on the P.W. board to obtain 3.5 kHz deviation.



8.3 RX ADJUSTMENTS

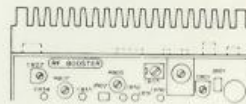
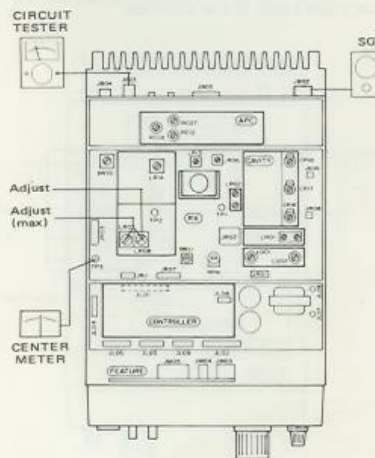
1. IF ADJUSTMENTS

(CONDITIONS)

1. SENS. DX
2. SOL. MIN
3. PWR HI
4. VOL MIN
5. MODE FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP OFF
9. Power source 13.8 V
10. Dummy 4 Ω
11. Frequency 145.50 MHz
12. External Buck up SW. OFF

(PROCEDURES)

1. Set distortion meter or VTVM on a 1 V range, and maximize the noise level at SPK out by adjusting JR07 and LR08.
2. Connect center meter to TP3.
3. Apply a 60 dB unmodulated signal from SG.
4. Adjust LR08 for center meter to indicate ±0.



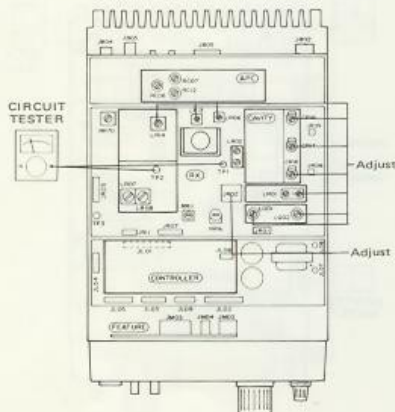
2. RF ADJUSTMENTS—PART 1

(CONDITIONS)

1. SENS. DX
2. SQL. MIN
3. PWR. HI
4. VOL. MIN
5. MODE. FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP. OFF
9. Power source 13.8 V
10. Dummy load. 4 Ω
11. Frequency 145.50 MHz
12. External Buck up SW. OFF

(PROCEDURES)

1. Connect a circuit tester to TP1 of RX PWB. Maximize the voltage at TP1 by adjusting LR02. (Repeat this procedure a few times.)
2. Connect a circuit tester to TP2, and apply a 60 dB unmodulated signal from SG. (A 0.1 V range.)
3. Repeat adjustment a few times to maximize voltages at LR14, LR13, LR06, CR18, CR17, CR16, LR01, LQ02, and LQ01, in that sequence.



RF ADJUSTMENTS – PART 2: CAVITY

(CONDITIONS)

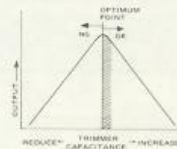
1. SENS. DX
2. SQL. MIN
3. PWR. HI
4. VOL. MIN
5. MODE. FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP. OFF
9. Power source 13.8 V
10. Dummy load. 4 Ω
11. Frequency 145.50 MHz
12. External Buck up SW. OFF

(PROCEDURES)

NOTE:

Do not conduct these adjustments except when trimmers are replaced, or similar.

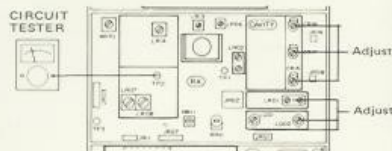
1. Connect a circuit tester to TP2 on the signal side.
2. After adjusting per RF adjustments – part 1, again adjust the cavity trimmers.
3. Turn CR16 and CR18 by approximately 1 mm in the direction of increasing trimmer capacitance.
4. By CR17, adjust to maximize the output at TP2, taking care to adjust to a point where, with output remaining at maximum, trimmer capacitances are slightly on the higher side.



NOTE:

Never adjust for trimmer capacitances to be the lower side of the optimum point.

5. Adjust CR16 and CR18 similarly to 4).
6. Adjust CR17 similarly to 4).
7. Adjust LQ01, LQ02, and LR01 again to maximize the TP2 output.
8. Repeat adjustments per 3) – 6).
9. Switch to normal, and adjust to 20 dB using RR16 and for 0 dB with QS.
10. Switch RX sensitivity selector to local, and confirm that 20 dB QS is now 5 – 15 dB.
11. Switch RX sensitivity selector to DX, and confirm that 20 dB QS is now above –7 dB.



NOTE:

The three trimmers in the RX cavity have been factory adjusted before shipment and no further adjustments are required. Never touch these trimmers.

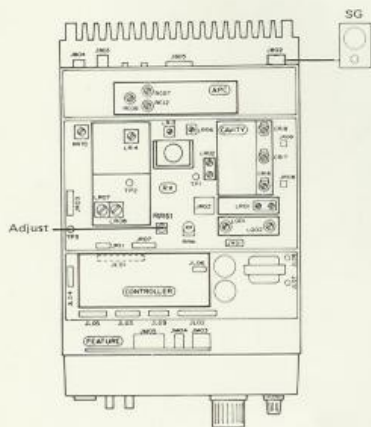
3. SQUELCH ADJUSTMENTS

(CONDITIONS)

1. SENS. DX
2. SQL. MIN
3. PWR. HI
4. VOL. MIN
5. MODE. FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP. OFF
9. Power source. 13.8 V
10. Dummy load. 4 Ω
11. Frequency. 145.50 MHz
12. External Buck up SW. OFF

(PROCEDURES)

1. Turn squelch volume control to the maximum.
2. Set SG for 1 kHz modulation at ±3.5 kHz deviation. Then set the SG attenuator to QS +5 dB.
3. While applying the above SG output, adjust RR61 for squelch to open.
4. Reduce the SG output for SQL to close, and reconfirm if it is accurately adjusted.
5. Then set SG for 2.5 kHz modulation at ±4 kHz deviation. Increase SG output and confirm that double squelch does not occur.



NOTE:

Increase the SG output to bring down the opening point of squelch. Although the closing point of squelch varies about 1~3 dB, tight squelch is obtained at the point at which the squelch opens with increased SG output.

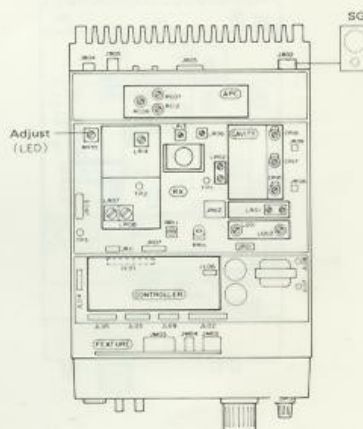
4. RX S METER ADJUSTMENTS

(CONDITIONS)

1. SENS. DX
2. SQL. MIN
3. PWR. HI
4. VOL. MIN
5. MODE. FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP. OFF
9. Power source. 13.8 V
10. Dummy load. 4 Ω
11. Frequency. 145.50 MHz
12. External Buck up SW. OFF

(PROCEDURES)

1. Set SG for no modulation -13 dB, and adjust RR70 for one of S meter LEDs to light up.
2. When varying SG output by SG attenuator, confirm that LEDs firing varies smoothly.
3. When one LED is fixed at -13 dB, turn RR70 to the extreme counterclockwise position, measure S meter sensitivity (the point where one LED lights up), and confirm that it is within -10 dB to -16 dB.



5. CHIP SWITCH ADJUSTMENTS

(CONDITIONS)

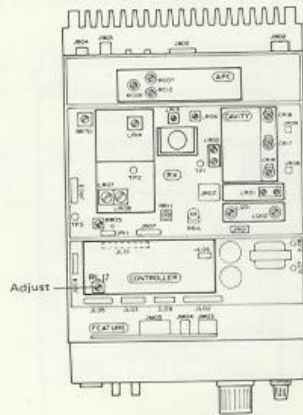
1. SENS. DX
2. SOL. MIN
3. PWR. HI
4. VOL. MIN
5. MODE FREE
6. SCAN. LOW
7. CH STEP. 25 kHz
8. BUCK UP OFF
9. Power source 9.5 V

(PROCEDURES)

1. Set power supply voltage at 9.5 V.

NOTE:

- Use reliable equipment to get exactly 9.5 V.
2. Adjust RL117 trimmer in the PL01 board for the frequency display to just disappear.
 3. Set power supply voltage at 13.8 V. Then reduce this voltage slowly and confirm that as it hits 9.5 V frequency the display disappears.

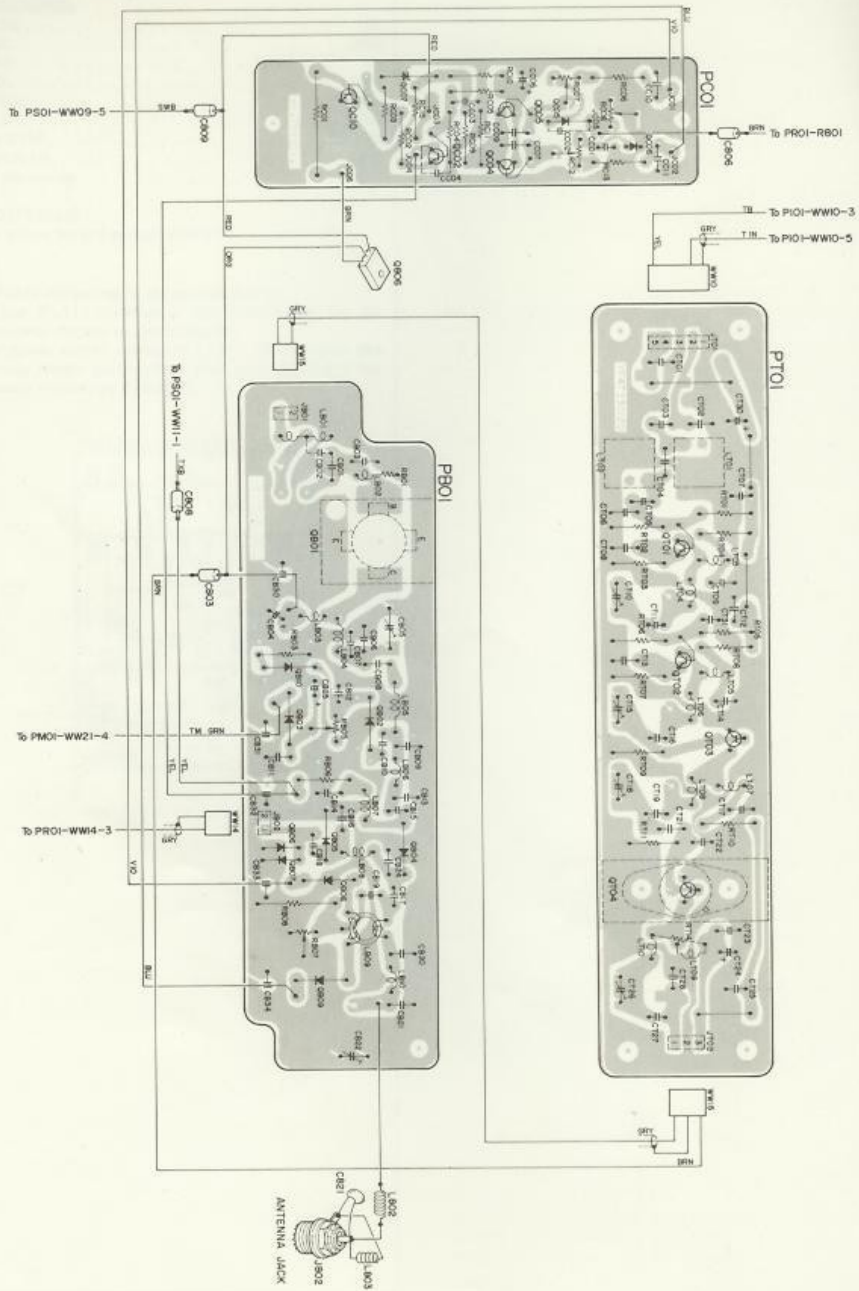


NOTE

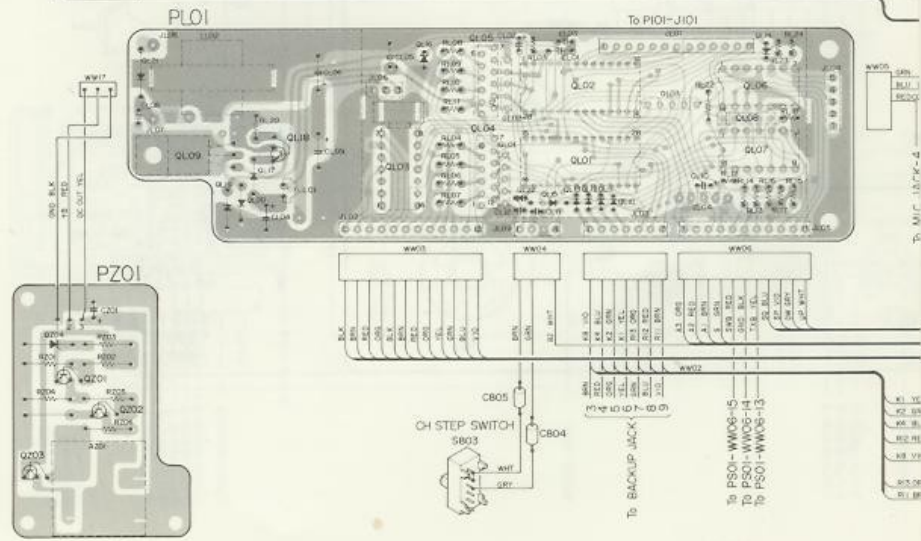
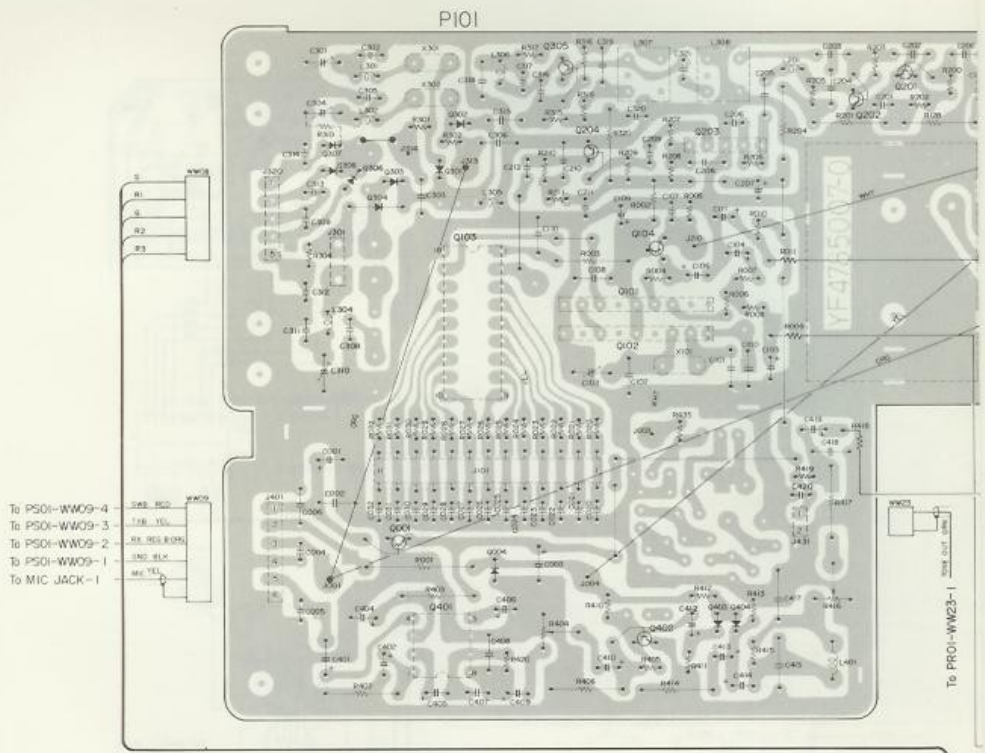
STANDARD DESIGN 2
MAY 1955 BY 12



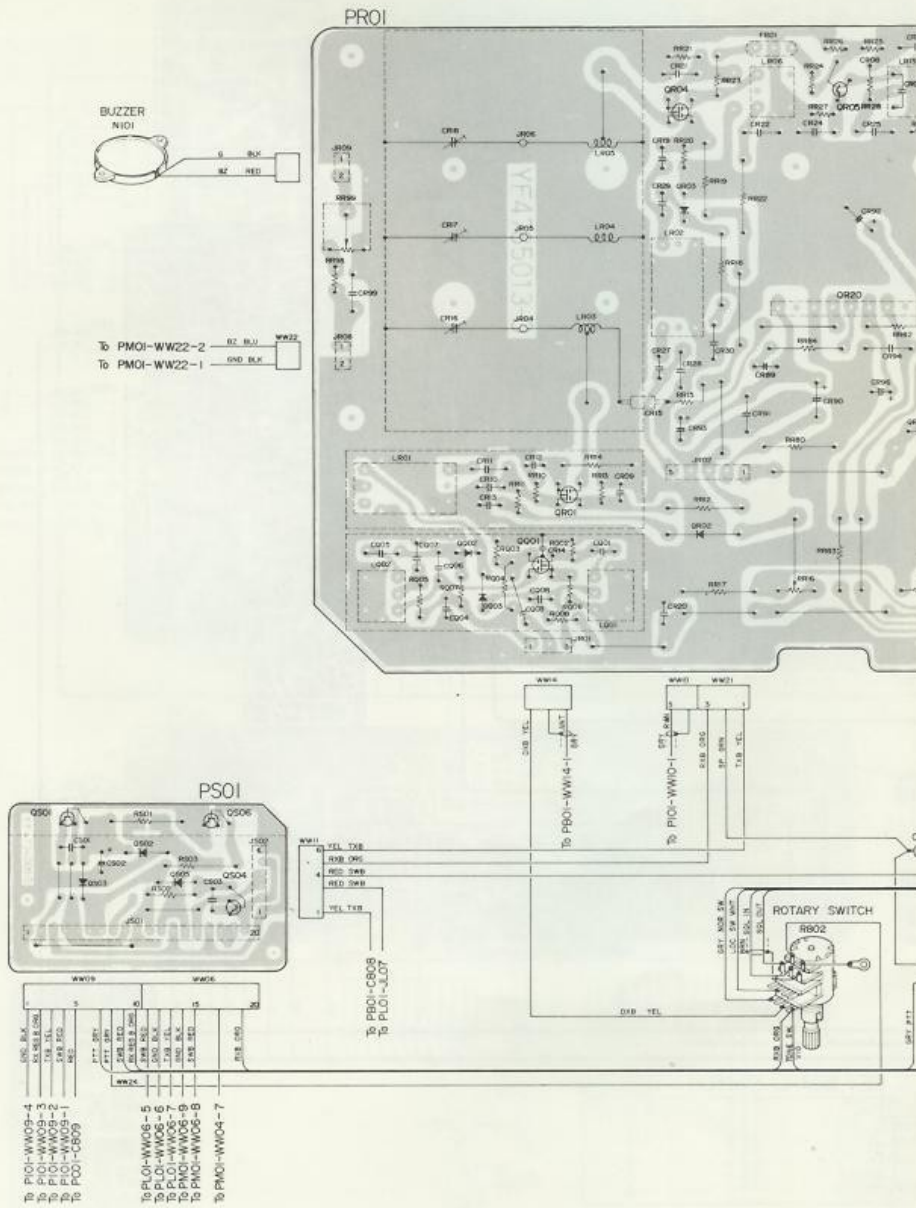
9. WIRING DIAGRAM
9.1 TX SECTION

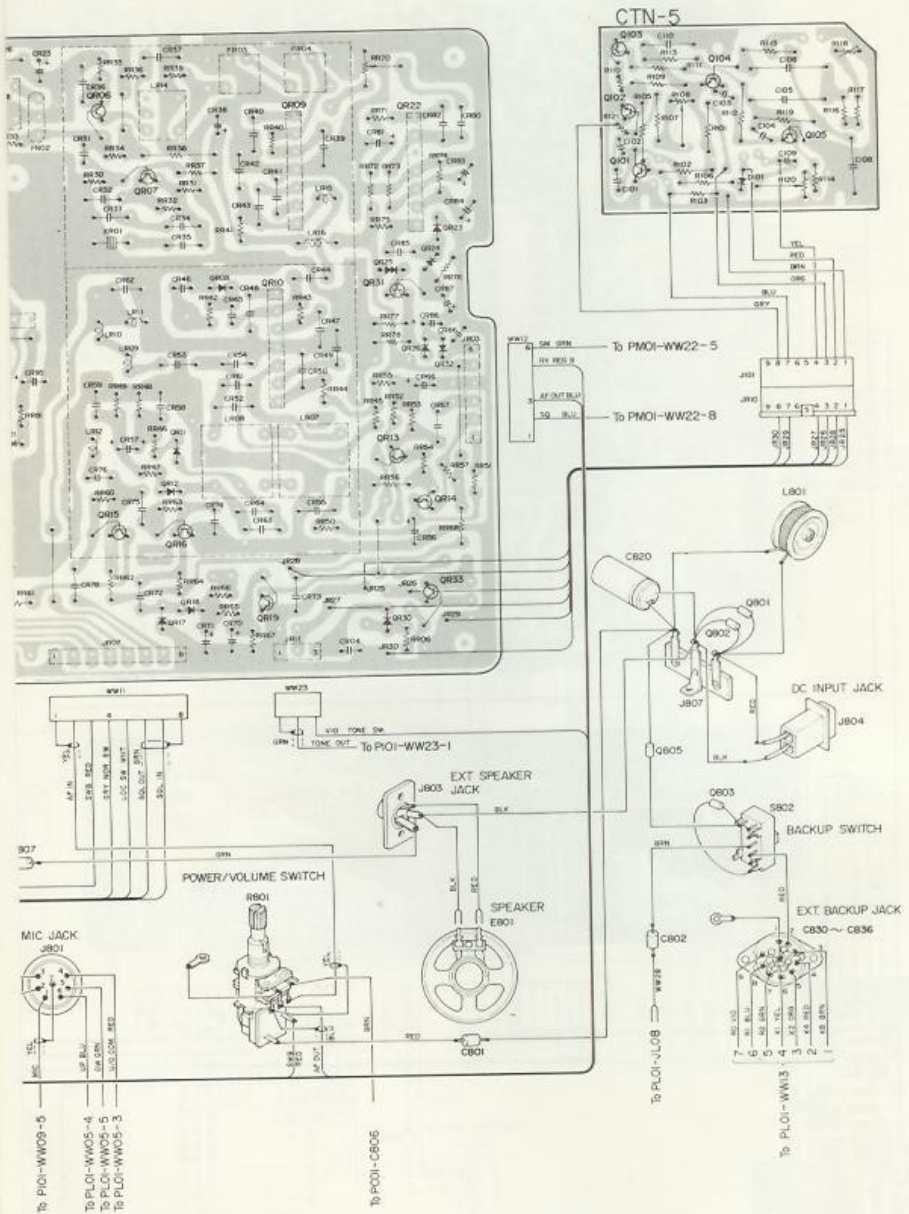


9.2 PLL SECTION

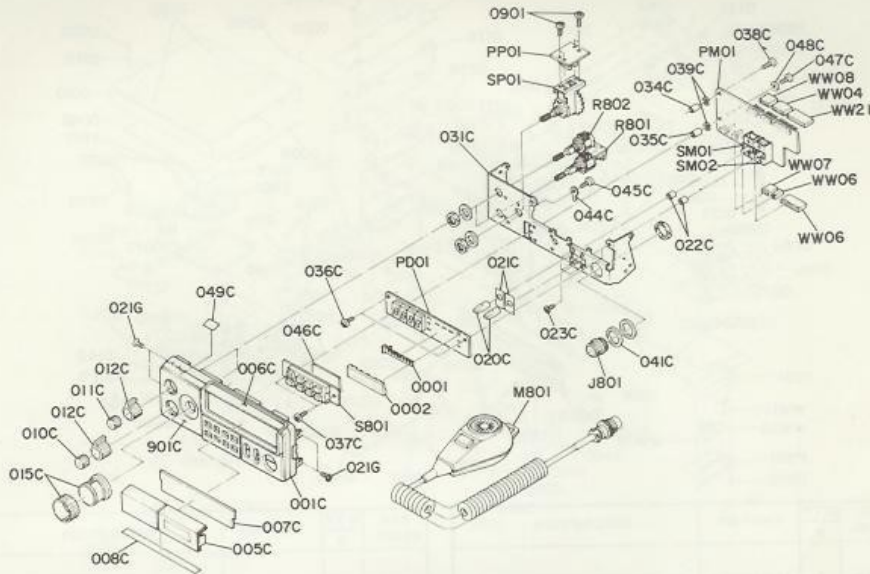


9.3 RX SECTION





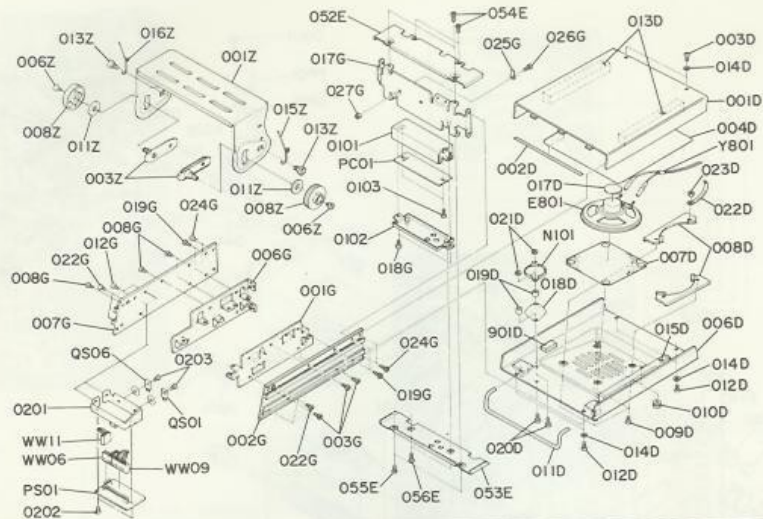
10. EXPLODED VIEWS AND PARTS LISTS
 10.1 [P01-99] ESCUTCHEON RELATED



REF. DESIG.	QTY N	PART NO.	DESCRIPTION
A	1	4785064410	Front Case Assembly
001C	1	4723064010	Front Case
005C	1	4723158040	Window
006C	1	4723303010	Mask
007C	1	4723158020	Window
008C	1	4723303020	Mask
049C	1	4723120060	Insulator
901C	1	4723063030	Escutcheon, Front Panel
002C	1	59020604P0	Washer
010C	1	4723154010	Knob, Volume
011C	1	4723154020	Knob, SQL
012C	2	4785154010	Knob, SENS/PWR
015C	1	4723154500	Knob, Rotary
020C	2	4723354010	Lever
021C	2	4723118030	Spacer
022C	2	4723118060	Spacer
023C	2	5104260480	F.H.M. Screw F2.6 x 4
031C	1	4723105010	Chassis, Front
034C	1	4723101010	Support
035C	1	4723101030	Support
036C	2	5110260580	B.H.M. Screw B2.6 x 5
037C	2	4723114020	Stopper
038C	1	5006260580	Screw 2.6 x 5
039C	2	54042602N0	Spring Washer
041C	1	4656118010	Spacer
044C	1	62030049W0	Lug
045C	1	5110030489	B.H.M. Screw B3 x 4
046C	1	4723120050	Insulator
047C	1	51100208B0	B.H.M. Screw B2 x 8
048C	1	59020605P0	Washer

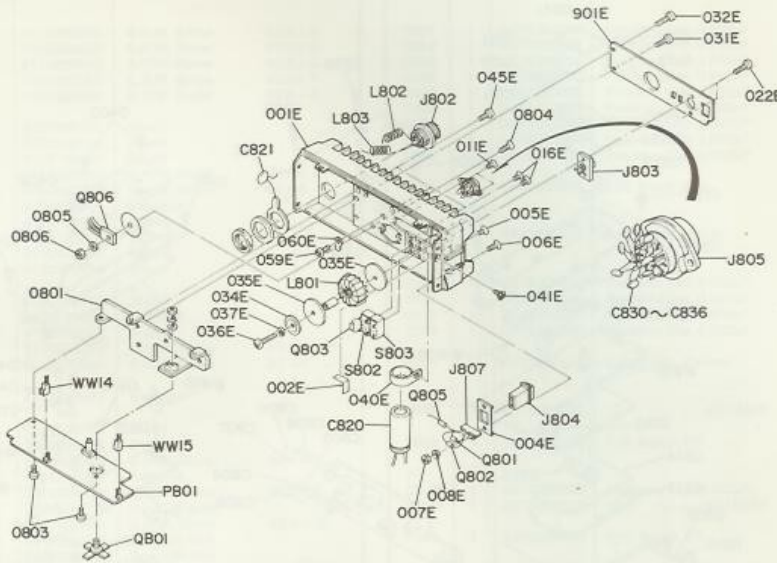
REF. DESIG.	QTY N	PART NO.	DESCRIPTION
021G	4	51042605E0	F.H.M. Screw F2.6 x 5
0901	4	51060308B9	P.H.M. Screw B3 x 8
M801	1	MP11000692	Microphone, MP716
2001	1	4785303010	Mask
2002	1	4785053010	Cover
J801	1	YJ10001250	Jack, Mic (7P)
R801	1	RD12030070	Variable Resistor, 20K Ω
R802	1	BR12030010	Variable Resistor, 20K Ω
S801	1	SK09080010	Keyboard Switch, (8 Key)
PD01	1	YF47230050	P.W. Board, Display
0001	1	4723118010	Spacer, LED
0002	1	4723053010	Cover, LED
PM01	1	YF47850080	P.W. Board, Feature
SM01	1	SC02030102	Switch
SM02	1	SC02020322	Switch
PP01	1	YF47230102	P.W. Board, Rotary Switch
SP01	1	SR24020010	Rotary Switch

10.2 [P02-99] CHASSIS RELATED



REF. DESIG.	QTY N	PART NO.	DESCRIPTION
001Z	1	4723160020	Bracket
003Z	2	4723051510	Guide Assembly
006Z	2	4723114010	Stopper
008Z	2	4723154100	Knob
011Z	2	4723118050	Spacer
013Z	2	4723271010	Holder
015Z	1	4723115010	Spring
016Z	1	4723115020	Spring
001D	1	4723257010	Lid, Top Cover
002D	1	4723118090	Spacer
003D	2	51280306U0	B.H. Tapped Screw B3 x 6
004D	1	4785853020	Label, Adjust Point
006D	1	4723257040	Lid, Bottom Cover
007D	1	4723202010	Net, Speaker
008D	2	4723005010	Clamper
009D	4	51100305H0	B.H.M. Screw B3 x 5
010D	2	4656259030	Bushing
011D	1	4723057010	Leg
012D	4	51280306U0	B.H. Tapped Screw B3 x 6
013D	2	4723056020	Buffer
014D	6	54020301S0	Flat Washer, P.
015D	1	4723056020	Buffer
017D	1	4736120010	Insulator
018D	1	4724202010	Net
019D	2	4724055010	Collar
020D	2	51100208S0	B.H.M. Screw B2 x 8
021D	2	53110203B0	Hexagon Nut
022D	1	4220005020	Clamper
023D	1	53110303B0	Hexagon Nut
901D	1	4785056020	Buffer Bottom Lid
052E	1	4723109210	Shield, Upper
053E	1	4723109220	Shield, Bottom
054E	4	51282606B0	B.H. Tapped Screw B2.6 x 6
055E	2	51102603B0	B.H.M. Screw B2.6 x 3
056E	2	51532606B0	P.H. Tapped Screw B2.6 x 6
001G	1	4723105020	Chassis, (R)
002G	1	4723051010	Guide, (R)
003G	4	51100304B9	B.H.M. Screw B3 x 4
006G	1	4723105030	Chassis, (L)
007G	1	4723051020	Guide, (L)
008G	4	51100304B9	B.H.M. Screw B3 x 4
012G	2	51100305B9	B.H.M. Screw B3 x 5
017G	1	4723126010	Stay
018G	2	51282605B0	B.H. Tapped Screw B2.6 x 5
019G	4	51280306B0	B.H. Tapped Screw B3 x 6
022G	4	51100305B9	B.H.M. Screw B3 x 5
024G	4	51280306B0	B.H. Tapped Screw B3 x 6
025G	1	62030039W0	Lug
026G	1	51102606B0	B.H.M. Screw B2.6 x 6
027G	1	53112603B0	Hexagon Nut
0101	1	4723109130	Shield
0102	1	4723109140	Shield
0103	2	51102605B0	B.H.M. Screw B2.6 x 5
0201	1	4723160030	Bracket
0202	2	51102605B0	B.H.M. Screw B2.6 x 5
0203	2	51102606B0	B.H.M. Screw B2.6 x 6
E801	1	QK008010B0	Speaker 1W 8Ω
N101	1	QK00245010	Buzzer
Y801	1	YB00150060	Connective Cord, Speaker
PC01	1	YF47230030	P.W. Board, Power Control
PS01	1	YF47240090	P.W. Board, Power Supply
QS01	1	HT313681B0	Transistor 2SC1368-B
QS06	1	HT70011100	Transistor JSP6009

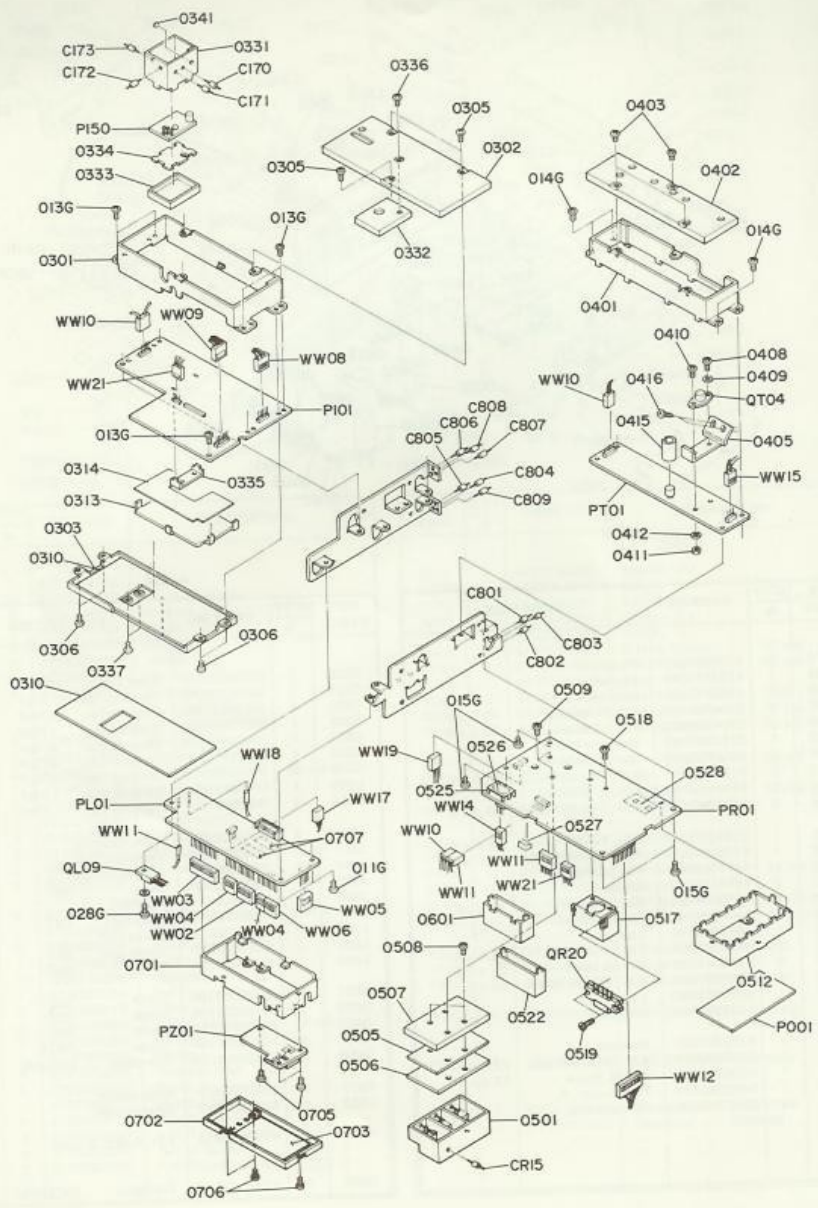
10.3 [P03-99] HEAT-SINK RELATED



REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
001E	1	4723267010	Heatsink
002E	1	4723120040	Insulator
004E	1	4723005020	Clamper
005E	1	51042606E0	F.H.M. Screw F2.6 x 6
006E	1	51042608E0	F.H.M. Screw F2.6 x 8
007E	1	53112603B0	Hexagon Nut
008E	1	54042602N0	Spring Washer
011E	2	51342606P0	F.H. Tapped Screw F2.6 x 6
016E	4	51041704E0	F.H.M. Screw F1.7 x 4
022E	2	51282608U0	B.H. Tapped Screw B2.6 x 8
031E	1	51282606U0	B.H. Tapped Screw B2.6 x 6
032E	1	51282610U0	B.H. Tapped Screw B2.6 x 10
034E	1	54110149A0	Fiat Washer, L.
035E	2	4618118040	Spacer
036E	1	5110031689	B.H.M. Screw B3 x 16
037E	1	54040302N0	Spring Washer
040E	1	4656005010	Clamper
041E	1	51042606E0	F.H.M. Screw F2.6 x 6
045E	3	5110041859	B.H.M. Screw B4 x 18
059E	1	51280305B0	B.H. Tapped Screw B3 x 5
060E	1	62030039W0	Lug
901E	1	4723265040	Indicator
0801	1	4723267020	Heatsink
0803	2	51282606B0	B.H. Tapped Screw B2.6 x 6
0804	1	51042615E0	F.H.M. Screw F2.6 x 15
0805	1	54022601B0	Fiat Washer, P.
0806	1	53112603B0	Hexagon Nut

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
C820	1	EG22802510	Elect Cap. 2200 μ F 25V
C821	1	DD15200300	Ceramic Cap. 20pF \pm 5%
C830	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C831	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C832	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C833	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C834	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C835	1	DK16471300	Ceramic Cap. 470pF \pm 10%
C836	1	DK16471300	Ceramic Cap. 470pF \pm 10%
J802	1	YJ10000780	Jack, Antenna
J803	1	YT02010080	Terminal, SPK
J804	1	YB00040010	Connector, DC
J805	1	YJ05000040	Jack, (9P)
J806	1	YP05000040	Plug (9P)
J807	1	YL01030210	Terminal, (3P)
L801	1	LC21240010	Choke Coil
L802	1	LC16000010	Choke Coil, (5T)
L803	1	LL22310100	Coil, (10T)
Q801	1	HD20001100	Diode 10D1
Q802	1	HD20001100	Diode 10D1
Q803	1	HD20023100	Diode 10E1
Q805	1	HD20001100	Diode 10D1
Q806	1	HT80053100	Transistor SJE5576
S802	1	S502020430	Slide Switch
S803	1	S502020430	Slide Switch
PB01	1	YF47230020	P.W. Board, Booster
Q801	1	HT321030A0	Transistor 25C2103A

10.4 [M01-99] VARIOUS BOARDS AND COMMON PARTS



REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
011G	2	5110260580	B.H.M. Screw B2.6 x 5
013G	5	5110260580	B.H.M. Screw B2.6 x 5
014G	4	5110260580	B.H.M. Screw B2.6 x 5
015G	4	5110260580	B.H.M. Screw B2.6 x 5
028G	1	5110260880	B.H.M. Screw B2.6 x 8
0301	1	4723109100	Shield
0302	1	4723109110	Shield
0303	1	4723109120	Shield
0305	3	5110020580	B.H.M. Screw B2 x 5
0306	4	5110020580	B.H.M. Screw B2 x 5
0310	2	4723120010	Insulator
0313	1	4785109010	Shield
0314	1	4785120010	Insulator
0331	1	4723109090	Shield
0332	1	4723109160	Shield
0333	1	4723109240	Shield
0334	1	4723120020	Insulator
0335	1	4723109250	Shield
0336	1	5110020380	B.H.M. Screw B2 x 3
0337	2	5110020380	B.H.M. Screw B2 x 3
0341	1	4723120080	Insulator
0401	1	4723109080	Shield
0402	1	4723109170	Shield
0403	3	5110020580	B.H.M. Screw B2 x 5
0405	1	4618267050	Heatsink
0408	1	5110260680	B.H.M. Screw B2.6 x 6
0409	1	54042602N0	Spring Washer
0410	1	5110261080	B.H.M. Screw B2.6 x 10
0411	1	5311260380	Hexagon Nut
0412	1	54042602N0	Spring Washer
0415	1	4723267050	Heatsink
0416	2	5128260680	B.H. Tapped Screw B2.6 x 6
0501	1	4723064500	Cavity Case Assembly
0505	1	4723109150	Shield
0506	1	4723277010	Packing
0507	1	4723257030	Lid, Cavity
0508	2	5110020680	B.H.M. Screw B2 x 6
0509	2	5110020880	B.H.M. Screw B2 x 8
0512	1	4785109500	IF Shield Assembly
0517	1	4723267030	Heatsink
0518	2	5110260580	B.H.M. Screw B2.6 x 5
0519	2	5110260880	B.H.M. Screw B2.6 x 8
0527	1	4785056010	Buffer
0522	1	4723109030	Shield, Frontend
0601	1	4723109040	Shield, Pre Amp.
0701	1	4723109190	Shield, Control
0702	1	4723109200	Shield, Control
0703	1	4723120030	Insulator
0705	3	5110260580	B.H.M. Screw B2.6 x 5
0706	3	5110020580	B.H.M. Screw B2 x 5
0707	2	4785120020	Insulator
0107	1	3730101020	Support
0108	1	3730101020	Support
0120	1	51100204E0	B.H.M. Screw B2 x 4
0121	1	51100204E0	B.H.M. Screw B2 x 4
0122	1	51100204E0	B.H.M. Screw B2 x 4
0525	1	4724109080	Shield, RX
0526	1	4724120010	Insulator, RX Shield
0528	1	4785120030	Insulator, RX IF Coil Case

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
C801	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C802	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C803	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C804	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C805	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C806	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C807	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C808	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C809	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
P101	1	YF47850070	P.W. Board, PLL
P150	1	YF47850010	P.W. Board, V.C.O.
C170	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C171	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C172	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
C173	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
PL01	1	YF47850110	P.W. Board, Control
QL09	1	HC10029060	IC μ PC14308
PR01	1	YF47850130	P.W. Board, RX
CR15	1	DC18202020	Feedthru Cap. 0.002 μ F 50V
QR20	1	HC10031010	IC HA1366W
PT01	1	YF47230120	P.W. Board, TX
QT04	1	HT321180A0	Transistor 2SC2118
PZ01	1	YF47230042	P.W. Board, Back Up

10.5 ELECTRICAL PARTS

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
P101	1	YF47850070	P.W. Board, PLL
P101-CAPACITORS			
C001	1	EA10702530	Elect 100µF 25V
C002	1	DK18103310	Ceramic 0.01µF
C003	1	EG33701620	Elect 330µF 16V
C004	1	DK16102300	Ceramic 0.001µF ±10%
C005	1	DK16471300	Ceramic 470pF ±10%
C006	1	DK16122300	Ceramic 0.0012µF ±10%
C020	1	DK16102300	Ceramic 0.001µF ±10%
C021	1	DK16102300	Ceramic 0.001µF ±10%
C022	1	DK16102300	Ceramic 0.001µF ±10%
C023	1	DK16102300	Ceramic 0.001µF ±10%
C024	1	DK16102300	Ceramic 0.001µF ±10%
C025	1	DK16102300	Ceramic 0.001µF ±10%
C026	1	DK16102300	Ceramic 0.001µF ±10%
C027	1	DK16102300	Ceramic 0.001µF ±10%
C028	1	DK16102300	Ceramic 0.001µF ±10%
C029	1	DK16102300	Ceramic 0.001µF ±10%
C030	1	DK16102300	Ceramic 0.001µF ±10%
C031	1	DK16102300	Ceramic 0.001µF ±10%
C032	1	DK16102300	Ceramic 0.001µF ±10%
C100	1	DD15300300	Ceramic 30pF ±5%
C101	1	DD15510300	Ceramic 51pF ±5%
C102	1	DD15150300	Ceramic 15pF ±5%
C103	1	CT12000090	Trimming 20pF
C104	1	EV10601060	Elect 10µF 10V
C105	1	EV10403560	Elect 0.1µF 35V
C106	1	EV47501060	Elect 4.7µF 10V
C107	1	DK16102300	Ceramic 0.001µF ±10%
C108	1	DS17104010	Semicon 0.1µF ±20%
C109	1	EA10701030	Elect 100µF 10V
C110	1	DS17683010	Semicon 0.068µF ±20%
C111	1	EA10701030	Elect 100µF 10V
C120	1	DK16102300	Ceramic 0.001µF ±10%
C121	1	DD15300330	Ceramic 30pF ±5%
C122	1	DD10010300	Ceramic 1pF ±0.25pF
C123	1	DK16102300	Ceramic 0.001µF ±10%
C124	1	DK16122300	Ceramic 0.0012µF ±10%
C125	1	DK16102300	Ceramic 0.001µF ±10%
C130	1	DD15300300	Ceramic 30pF ±5%
C131	1	DK16122300	Ceramic 0.0012µF ±10%
C132	1	DK16122300	Ceramic 0.0012µF ±10%
C133	1	EV22502560	Elect 2.2µF 25V
C134	1	DK16102300	Ceramic 0.001µF ±10%
C140	1	DD15300300	Ceramic 30pF ±5%
C141	1	DK16122300	Ceramic 0.0012µF ±10%
C142	1	DK16122300	Ceramic 0.0012µF ±10%
C143	1	DK16122300	Ceramic 0.0012µF ±10%
C144	1	DK16102300	Ceramic 0.001µF ±10%
C145	1	DK18102300	Ceramic 0.001µF 50V
C200	1	DD10030300	Ceramic 3pF ±0.25pF
C201	1	DK16102300	Ceramic 0.001µF ±10%
C202	1	DD10040300	Ceramic 4pF ±0.25pF
C203	1	DK16471300	Ceramic 470pF ±10%
C204	1	DK16122300	Ceramic 0.0012µF ±10%
C205	1	DD15101350	Ceramic 100pF ±5%
C206	1	DK16102300	Ceramic 0.001µF ±10%
C207	1	EA47601030	Elect 47µF 10V
C208	1	DK18103310	Ceramic 0.01µF
C209	1	DK16102300	Ceramic 0.001µF ±10%
C210	1	DK16122300	Ceramic 0.0012µF ±10%
C211	1	DK16102300	Ceramic 0.001µF ±10%
C212	1	DK16102300	Ceramic 0.001µF ±10%
C213	1	DD15470300	Ceramic 470pF

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
C301	1	CT12000090	Trimming 20pF
C302	1	DD10020350	Ceramic 2pF ±0.25pF
C303	1	DK16122300	Ceramic 0.0012µF ±10%
C304	1	CT12000090	Trimming 20pF
C305	1	DD10020350	Ceramic 2pF ±0.25pF
C306	1	DK16122300	Ceramic 0.0012µF ±10%
C309	1	DK16102300	Ceramic 0.001µF ±10%
C310	1	CT12000090	Trimming 20pF
C311	1	DD10020350	Ceramic 2pF ±0.25pF
C312	1	DK16102300	Ceramic 0.001µF ±10%
C313	1	DK16102300	Ceramic 0.001µF ±10%
C314	1	DK16102300	Ceramic 0.001µF ±10%
C315	1	DK16122300	Ceramic 0.0012µF ±10%
C316	1	DD15101050	Ceramic 100pF ±5%
C317	1	DD15620010	Ceramic 62pF ±5%
C318	1	DK18103310	Ceramic 0.01µF
C319	1	DK18103310	Ceramic 0.01µF
C320	1	DK16102300	Ceramic 0.001µF ±10%
C321	1	DD10010300	Ceramic 1pF ±0.25pF
C401	1	EV33403560	Elect 0.33µF 35V
C402	1	EV47600660	Elect 47µF 6.3V
C404	1	EA22701030	Elect 220µF 10V
C405	1	EV10502560	Elect 1µF 25V
C406	1	EV22601060	Elect 22µF 10V
C407	1	DS17222010	Semicon 0.0022µF ±20%
C408	1	DK18103310	Ceramic 0.01µF
C409	1	EV10502560	Elect 1µF 25V
C410	1	EV10403560	Elect 0.1µF 35V
C412	1	EA10601690	Elect 10µF 16V
C413	1	EA10601690	Elect 10µF 16V
C414	1	EV10502560	Elect 1µF 25V
C415	1	DF16683300	Film 0.068µF ±10%
C417	1	DF16683300	Film 0.068µF ±10%
C418	1	DF16103300	Film 0.01µF ±10%
C419	1	EV10601060	Elect 10µF 10V
C420	1	DK16102300	Ceramic 0.001µF ±10%
P101-RESISTORS (All Resistors are ±5% and 1/4W)			
R001	1	GJ05680010	68Ω
R002	1	GD05101140	100Ω
R003	1	GD05101140	100Ω
R004	1	GD05272140	2.7KΩ
R005	1	GD05222140	2.2KΩ
R006	1	GD05272140	2.7KΩ
R007	1	GD05272140	270Ω
R008	1	GD05682140	6.8KΩ
R009	1	GD05333140	33KΩ
R010	1	GD05101140	100Ω
R011	1	RC00000120	0Ω
R020	1	GD05682140	6.8KΩ
R021	1	GD05682140	6.8KΩ
R022	1	GD05682140	6.8KΩ
R023	1	GD05682140	6.8KΩ
R024	1	GD05682140	6.8KΩ
R025	1	GD05682140	6.8KΩ
R026	1	GD05682140	6.8KΩ
R027	1	GD05682140	6.8KΩ
R028	1	GD05682140	6.8KΩ

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
R029	1	GD05682140	6.8K Ω
R030	1	GD05682140	6.8K Ω
R031	1	GD05682140	6.8K Ω
R032	1	GD05682140	6.8K Ω
R120	1	GD05103140	10K Ω
R121	1	GD05103140	10K Ω
R122	1	GD05561140	560 Ω
R123	1	GD05101140	100 Ω
R124	1	GD05103140	10K Ω
R125	1	GD05153140	15K Ω
R126	1	GD05471140	470 Ω
R127	1	GD05101140	100 Ω
R128	1	GD05101140	100 Ω
R130	1	GD05102140	1K Ω
R131	1	GD05472140	4.7K Ω
R132	1	GD05331140	330 Ω
R133	1	GD05101140	100 Ω
R134	1	GD05472140	4.7K Ω
R135	1	GD05102140	1K Ω
R136	1	RA04720050	4.7K Ω Trimming
R137	1	RC00000120	0 Ω
R140	1	GD05102140	1K Ω
R141	1	GD05472140	4.7K Ω
R142	1	GD05331140	330 Ω
R143	1	GD05101140	100 Ω
R144	1	GD05561140	560 Ω
R145	1	GD05333140	33K Ω
R200	1	GD05224140	220K Ω
R201	1	GD05101140	100 Ω
R202	1	GD05561140	560 Ω
R203	1	GD05154140	150K Ω
R204	1	GD05101140	100 Ω
R206	1	GD05472140	4.7K Ω
R206	1	GD05272140	2.7K Ω
R207	1	GD05102140	1K Ω
R208	1	GD05101140	100 Ω
R209	1	GD05154140	150K Ω
R210	1	GD05561140	560 Ω
R211	1	GD05101140	100 Ω
R301	1	GD05272140	2.7K Ω
R302	1	GD05272140	2.7K Ω
R304	1	GD05272140	2.7K Ω
R310	1	GD05272180	2.7K Ω 1/8W
R311	1	GD05272180	2.7K Ω 1/8W
R315	1	GD05182140	1.8K Ω
R316	1	GD05152140	1.5K Ω
R317	1	GD05471140	470 Ω
R319	1	GD05101140	100 Ω
R320	1	GD05101140	100 Ω
R402	1	GD05105140	1M Ω
R403	1	GD05680140	68 Ω
R404	1	RA02220100	2.2K Ω Trimming
R405	1	GD05223140	22K Ω
R406	1	GD05153140	15K Ω
R410	1	GD05222140	2.2K Ω

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
R411	1	GD05272140	2.7K Ω
R412	1	GD05272140	2.7K Ω
R413	1	GD05332140	3.3K Ω
R414	1	GD05561140	560 Ω
R415	1	GD05562140	5.6K Ω
R416	1	RA01030070	10K Ω Trimming
R417	1	GD05272140	2.7K Ω
R418	1	RC00000120	0 Ω
R419	1	GD05333140	33K Ω
R420	1	GD05472140	4.7K Ω
Q001	1	HC10022060	P101-SEMICONDUCTORS IC μ PC78L08
Q004	1	HD30017090	Zener BZ-090
Q101	1	HC10046050	IC TC5081P
Q102	1	HC10023050	IC TC5082PL
Q103	1	HC10047050	IC TC9122P
Q104	1	HT10733180	Transistor 2SA733(R)
Q120	1	HT30461180	Transistor 2SC461(B)
Q121	1	HT30461180	Transistor 2SC461(B)
Q122	1	HT30461180	Transistor 2SC461(B)
Q123	1	HT30461180	Transistor 2SC461(B)
Q124	1	HT31213180	Transistor 2SC1213(B)
Q125	1	HT30945100	Transistor 2SC945(Q)
Q126	1	HT30945100	Transistor 2SC945(Q)
Q201	1	HT30461180	Transistor 2SC461(B)
Q202	1	HT30461180	Transistor 2SC461(B)
Q203	1	HC10017210	IC BA401
Q204	1	HT30460180	Transistor 2SC460(B)
Q301	1	HD20011050	Diode 1S1555
Q302	1	HD20011050	Diode 1S1555
Q304	1	HD20011050	Diode 1S1555
Q305	1	HT30460180	Transistor 2SC460(B)
Q306	1	HD20011050	Diode 1S1555
Q307	1	HD20011050	Diode 1S1555
Q308	1	HD20011050	Diode 1S1555
Q401	1	HC10001390	IC SL-1626C
Q402	1	HT309001F0	Transistor 2SC900(F)
Q403	1	HD20011050	Diode 1S1555
Q404	1	HD20011050	Diode 1S1555
J101	1	YP06001540	P101-MISCELLANEOUS Plug, Program
J125	1	YP06001200	Plug, PLL Output
J301	1	YJ03000050	Jack, X'tal Socket
J320	1	YP06001200	Plug, X'tal SW.
J401	1	YP06000880	Plug, Power In
J431	1	YP06001480	Plug, 5045-02A (CTN-5)

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
L120	1	LA70280010	Ant. Coil, TX PLL Out
L121	1	LA70280050	Ant. Coil, RX PLL Out
L122	1	LA70280060	Ant. Coil, VCO
L201	1	LC11530020	Choke Coil, 15 μ H
L202	1	LC12720020	Choke Coil, 2.7 μ H
L301	1	LC11020020	Choke Coil, 1 μ H
L302	1	LC11020020	Choke Coil, 1 μ H
L304	1	LC11020020	Choke Coil, 1 μ H
L305	1	LC13940010	Choke Coil, 390 μ H
L306	1	LC11020020	Choke Coil, 1 μ H
L307	1	LA70280050	Ant. Coil, PLL Local OSC
L308	1	LO70280010	OSC Coil, PLL Local OSC
L401	1	LC24760010	Choke Coil, 47mH
X101	1	XY40512002	Cristal 5.12MHz
X301	1	XB301010G2	Cristal 46.000MHz, TX
X302	1	XB301011G2	Cristal 42.433MHz, RX
P150	1	YF47850010	P150-VCO CIRCUIT BOARD P.W. Board, VCO
P150-CAPACITORS			
C150	1	DK16102300	Ceramic 0.001 μ F \pm 10%
C151	1	DK16102300	Ceramic 0.001 μ F \pm 10%
C152	1	EA10602530	Elect. 10 μ F 25V
C153	1	DD10030300	Ceramic 3pF \pm 0.25pF
C154	1	DD11100300	Ceramic 10pF \pm 0.5pF
C155	1	DD11100300	Ceramic 10pF \pm 0.5pF
C156	1	DD15240300	Ceramic 24pF \pm 5%
C157	1	DD10010300	Ceramic 1pF \pm 0.25pF
C158	1	DD15390300	Ceramic 39pF \pm 5%
C159	1	DS17392010	Semicon 3900pF \pm 20%
C160	1	EV33601060	Elect. 33 μ F 10V
C170	1	DC18202020	Feedthru 2000pF
C171	1	DC18202020	Feedthru 2000pF
C172	1	DC18202020	Feedthru 2000pF
C173	1	DC18202020	Feedthru 2000pF
P150-RESISTORS (All Resistors are \pm 5% and $\frac{1}{4}$ W)			
R150	1	GD05101140	100 Ω
R151	1	GD05101140	100 Ω
R152	1	GD05101140	100 Ω
R153	1	GD05222140	2.2K Ω
R154	1	GD05473140	47K Ω
R155	1	GD05103140	10K Ω
R156	1	GD05104140	100K Ω
P150-SEMICONDUCTORS			
Q151	1	HD40001060	Varicap 1SV50
Q152	1	HD40001060	Varicap 1SV50
Q153	1	HD40001060	Varicap 1SV50
Q154	1	HF20019180	F.E.T. 2SK19TM(GR)
P150-COILS			
L150	1	LA12036060	Ant. Coil, VCO
L151	1	LC12720020	Choke Coil, 2.7 μ H
L152	1	LC11020020	Choke Coil, 1 μ H
L153	1	LC11020020	Choke Coil, 1 μ H

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PB01	1	YF47230020	PB01-BOOSTER CIRCUIT BOARD P.W. Board, Booster
PB01-CAPACITORS			
CB01	1	CT11050010	Trimming 12pF
CB02	1	DD15510300	Ceramic 51pF \pm 5%
CB03	1	DD15150300	Ceramic 15pF \pm 5%
CB04	1	EG47503520	Elect. 4.7 μ F 35V
CB05	1	CT11500010	Trimming 15pF
CB06	1	DD15180300	Ceramic 15pF \pm 5%
CB07	1	DD15200300	Ceramic 20pF \pm 5%
CB08	1	DD15150300	Ceramic 15pF \pm 5%
CB09	1	DD15150300	Ceramic 15pF \pm 5%
CB10	1	DD10005010	Ceramic 0.5pF \pm 0.25pF
CB11	1	DK16122300	Ceramic 0.0012 μ F \pm 10%
CB12	1	DK16102300	Ceramic 0.001 μ F \pm 10%
CB13	1	DD15300300	Ceramic 30pF \pm 5%
CB14	1	DK18103310	Ceramic 0.01 μ F \pm 100% -0
CB15	1	DK16471300	Ceramic 470pF \pm 10%
CB16	1	DD15200300	Ceramic 20pF \pm 5%
CB17	1	DK16471300	Ceramic 470pF \pm 10%
CB18	1	DK16471300	Ceramic 470pF \pm 10%
CB19	1	DD10030300	Ceramic 3pF \pm 0.25pF
CB20	1	DD15300300	Ceramic 30pF \pm 5%
CB21	1	DD15200300	Ceramic 20pF \pm 5%
CB22	1	CT11050010	Trimming 12pF
CB24	1	DD15200300	Ceramic 20pF \pm 5%
CB25	1	EV33502560	Elect. 3.3 μ F 25V
CB30	1	DC18202020	Feedthru 2000pF
CB31	1	DC18202020	Feedthru 2000pF
CB32	1	DC18202020	Feedthru 2000pF
CB33	1	DC18202020	Feedthru 2000pF
CB34	1	DC18202020	Feedthru 2000pF
PB01-RESISTORS			
RB01	1	GD05020140	2 Ω \pm 5% $\frac{1}{4}$ W
RB02	1	GD05331140	330 Ω \pm 5% $\frac{1}{4}$ W
RB03	1	GD05101140	100 Ω \pm 5% $\frac{1}{4}$ W
RB05	1	RA01040120	100K Ω Trimming $\frac{1}{4}$ W
RB06	1	GD05331140	330 Ω \pm 5% $\frac{1}{4}$ W
RB07	1	RA01020150	1K Ω Trimming $\frac{1}{4}$ W
RB08	1	GF05101120	100 Ω \pm 5% $\frac{1}{4}$ W
RB09	1	RC00000140	0 Ω
RB10	1	RC00000140	0 Ω
RB11	1	RC00000140	0 Ω
RB12	1	RC00000140	0 Ω
RB13	1	RC00000140	0 Ω
PB01-SEMICONDUCTORS			
QB01	1	HT321030A0	Transistor 2SC2103A
QB02	1	HD20011050	Diode 1S1555
QB03	1	HD10001050	Diode 1N60
QB04	1	HD20003200	Diode M1402
QB05	1	HD20001200	Diode M1301
QB06	1	HD20011050	Diode 1S1555
QB07	1	HD20011050	Diode 1S1555
QB08	1	HD10001050	Diode 1N60
QB09	1	HD10001050	Diode 1N60
QB10	1	HD30033090	Zener WZ-052

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
PB01-MISCELLANEOUS			
JB01	1	YP06001480	Plug (2P)
JB02	1	YP06001480	Plug (2P)
LB01	1	LM42830010	Twist Coil
LB02	1	LC12010012	Choke Coil (8T) 0.2μH
LB03	1	LC16000010	Choke Coil (5T)
LB04	1	LC12500020	Choke Coil (1T)
LB05	1	LK30802040	Coil (4T)
LB06	1	LC16000010	Choke Coil (5T)
LB07	1	LL26301050	Coil (8T)
LB08	1	LC11510012	Choke Coil (3T)
LB09	1	LF50080030	Ant. Coil
LB10	1	LC16000010	Choke Coil (5T)
PC01-POWER CONTROL CIRCUIT BOARD			
PC01	1	YF47230030	P.W. Board, Power Control
PC01-CAPACITORS			
CC01	1	DK16102300	Ceramic 0.001μF ±10%
CC02	1	DK16102300	Ceramic 0.001μF ±10%
CC03	1	DK16102300	Ceramic 0.001μF ±10%
CC04	1	DK16102300	Ceramic 0.001μF ±10%
CC05	1	DK16102300	Ceramic 0.001μF ±10%
CC06	1	EG47503520	Elect 4.7μF 35V
CC07	1	DK18103310	Ceramic 0.01μF +100% -0
CC09	1	DK18103310	Ceramic 0.01μF +100% -0
CC10	1	DK18103310	Ceramic 0.01μF +100% -0
CC11	1	DK18103310	Ceramic 0.01μF +100% -0
PC01-RESISTORS			
(All Resistors are ±5% and 1/8W)			
RC01	1	GJ05121020	120Ω 2W
RC02	1	GD05151140	150Ω
RC03	1	GD05222140	2.2KΩ
RC04	1	GD05334140	330KΩ
RC05	1	GD05473140	47KΩ
RC06	1	GD05222140	2.2KΩ
RC07	1	RA02220100	2.2KΩ Trimming
RC08	1	RA05030110	47KΩ Trimming
RC09	1	GD05471140	470Ω
RC10	1	GD05104140	100KΩ
RC11	1	GD05100140	10Ω
RC12	1	RA05030110	47KΩ Trimming
RC13	1	GD05682140	6.8KΩ
RC15	1	GD05101140	100Ω
PC01-SEMICONDUCTORS			
QC01	1	HT40471110	Transistor 2SD471
QC02	1	HT30460180	Transistor 2SC460(B)
QC03	1	HT30460180	Transistor 2SC460(B)
QC04	1	HT30460180	Transistor 2SC460(B)
QC05	1	HD20001210	Diode 1S2473
QC06	1	HD20001210	Diode 1S2473
QC07	1	HD30017090	Zener BZ-090

REF. DESIG.	Q'TY N	PART NO.	DESCRIPTION
PD01-DISPLAY CIRCUIT BOARD			
PD01	1	YF47230050	P.W. Board, Display
PD01-CAPACITOR			
CD01	1	DK16471300	Ceramic 470pF ±10%
PD01-RESISTORS			
RD02	1	GD05682180	6.8KΩ ±5% 1/8W
RD03	1	GD05123180	12KΩ ±5% 1/8W
PD01-SEMICONDUCTORS			
QD01	1	H110006030	L.E.D. 75EG, Green
QD02	1	H110006030	L.E.D. 75EG, Green
QD03	1	H110006030	L.E.D. 75EG, Green
QD04	1	H110006030	L.E.D. 75EG, Green
QD05	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD06	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD07	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD08	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD09	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD10	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD11	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD12	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD13	1	H110002340	L.E.D. HP-5082-4150, Yellow
QD14	1	H110003340	L.E.D. HP-5082-4100, Read
QD15	1	H110003340	L.E.D. HP-5082-4100, Read
QD16	1	H110003340	L.E.D. HP-5082-4100, Read
QD17	1	HD20001210	Diode 1S2473
QD18	1	HD20001210	Diode 1S2473
QD19	1	HD20001210	Diode 1S2473
QD20	1	HC10001380	IC UAA-180
QD21	1	HV00002060	Varistor VD1212
PL01-CONTROL CIRCUIT BOARD			
PL01	1	YF47850110	P.W. Board, Control
CL01-CAPACITORS			
CL01	1	DD15330300	Ceramic 33pF ±5%
CL02	1	EV22501660	Elect 2.2μF 16V
CL03	1	DK16102300	Ceramic 0.001μF ±10%
CL04	1	EA22701630	Elect 220μF 16V
CL05	1	EA33701030	Elect 330μF 10V
CL06	1	EG10801620	Elect 1000μF 16V
CL07	1	DK16471300	Ceramic 470pF ±10%
CL08	1	DK16471300	Ceramic 470pF ±10%
CL09	1	EG10801620	Elect 1000μF 16V
CL10	1	EV10503560	Elect 1μF 35V
CL11	1	DK16471300	Ceramic 470pF ±10%
CL12	1	DK16471300	Ceramic 470pF ±10%
PL01-RESISTORS			
(All Resistors are ±5% and 1/8W)			
RL03	1	GD05473140	47KΩ
RL04	1	GU05330120	33Ω 1/8W
RL05	1	GU05330120	33Ω 1/8W
RL06	1	GU05330120	33Ω 1/8W
RL07	1	GU05330120	33Ω 1/8W
RL08	1	GU05330120	33Ω 1/8W
RL09	1	GU05330120	33Ω 1/8W
RL10	1	GU05330120	33Ω 1/8W
RL11	1	GU05330120	33Ω 1/8W
RL12	1	GD05562140	5.6KΩ

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
RL13	1	GD05223140	22K Ω
RL14	1	GD05333140	33K Ω
RL15	1	GD05185140	1.8M Ω
RL16	1	GD05333140	33K Ω
RL17	1	RA04730100	47K Ω Trimming
RL18	1	GD05333140	33K Ω
RL20	1	GD05471140	470 Ω
RL22	1	GD05562140	5.6K Ω
RL23	1	GD05333140	33K Ω
RL24	1	GD05333140	33K Ω
GL01	1	BW10333010	33K Ω x 4 10% R-Block
GL02	1	BW10333010	33K Ω x 4 10% R-Block
GL03	1	BW10333010	33K Ω x 4 10% R-Block
GL04	1	BW10333010	33K Ω x 4 10% R-Block
PL01-SEMICONDUCTORS			
QL01	1	HC10003370	IC MP1107
QL02	1	HC10005370	IC TMS1024
QL03	1	HC10016060	IC μ PA57C
QL04	1	HC10011210	IC TA76
QL05	1	HC10011210	IC TA76
QL06	1	HC10012170	IC MC14016
QL07	1	HC10012170	IC MC14016
QL08	1	HD20401210	Diode DAP401
QL09	1	HC10029060	IC μ PC14308
QL10	1	HC20011050	Diode 1S1555
QL11	1	HC20011050	Diode 1S1555
QL12	1	HC20011050	Diode 1S1555
QL13	1	HC20011050	Diode 1S1555
QL14	1	HC20011050	Diode 1S1555
QL15	1	HC20011050	Diode 1S1555
QL16	1	HC20011050	Diode 1S1555
QL17	1	HC20011050	Diode 1S1555
QL18	1	HT31213180	Transistor 2SC1213B
QL19	1	HD30060090	Zener XZ094
QL20	1	HD20011050	Diode 1S1555
QL21	1	HD20001100	Diode 10D-2
QL22	1	HD20011050	Diode 1S1555
PL01-MISCELLANEOUS			
JL01	1	YJ06002100	Jack (13P)
JL02	1	YP06001160	Plug (12P)
JL03	1	YP06001800	Plug (7P)
JL04	1	YP06001200	Plug (5P)
JL05	1	YP06001280	Plug (11P)
JL06	1	YP06000890	Plug (3P)
JL07	1	YP10002210	Plug (1P)
JL08	1	YP10002210	Plug (1P)
JL09	1	YP06001820	Plug (4P)
LL01	1	LC13940010	Choke Coil, 390 μ H
LL02	1	LC26550010	Choke Coil, 6.4mH
PM01-FEATURE CONTROL CIRCUIT BOARD			
PM01	1	YF47850080	P.W. Board, Feature Control
PM01-CAPACITORS			
CM01	1	DK18103310	Ceramic 0.01 μ F
CM02	1	DS17153010	Semicon 0.015 μ F \pm 20%
CM03	1	EV10403560	Elect 0.1 μ F 35V
CM04	1	EV10403560	Elect 0.1 μ F 35V
CM05	1	DD15101370	Ceramic 100pF \pm 5%

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
CM06	1	DD15101370	Ceramic 100pF \pm 5%
CM07	1	EV33502560	Elect 3.3 μ F 25V
CM08	1	EV33502560	Elect 3.3 μ F 25V
CM09	1	EV22601660	Elect 22 μ F 16V
CM10	1	DK18103310	Ceramic 0.01 μ F
CM15	1	EV10502560	Elect 1 μ F 25V
PM01-RESISTORS (All Resistors are \pm 5% and 1/8W)			
RM02	1	GD05102180	1K Ω
RM03	1	GD05103180	10K Ω
RM04	1	GD05103180	10K Ω
RM05	1	GD05103180	10K Ω
RM06	1	GD05473180	47K Ω
RM07	1	GD05473180	47K Ω
RM08	1	GD05473180	47K Ω
RM09	1	GD05473180	47K Ω
RM11	1	GD05223180	22K Ω
RM12	1	GD05103180	10K Ω
RM13	1	GD05822180	8.2K Ω
RM14	1	GD05103180	10K Ω
RM15	1	GD05473180	47K Ω
RM16	1	GD05333180	33K Ω
RM17	1	GD05333180	33K Ω
RM18	1	GD05102180	1K Ω
RM19	1	GD05102180	1K Ω
RM20	1	GD05392180	3.9K Ω
RM21	1	GD05392180	3.9K Ω
RM22	1	GD05682180	6.8K Ω
RM23	1	GD05682180	6.8K Ω
RM24	1	GD05392180	3.9K Ω
RM25	1	GD05392180	3.9K Ω
RM26	1	GD05562180	5.6K Ω
RM27	1	GD05562180	5.6K Ω
RM28	1	GD05222180	2.2K Ω
RM29	1	GD05682140	6.8K Ω %W
RM30	1	GD05222180	2.2K Ω
PM01-SEMICONDUCTORS			
QM02	1	HC10014170	IC MC14011BP
QM03	1	HC10021050	IC TC7400
QM04	1	HC10021050	IC TC7400
QM05	1	HC10014170	IC MC14011BP
QM06	1	HC10022060	IC μ PC78L08
QM07	1	HT320211R2	Transistor 2SC2021
QM08	1	HT320211R2	Transistor 2SC2021
QM09	1	HT320211R2	Transistor 2SC2021
QM10	1	HT320211R2	Transistor 2SC2021
QM11	1	HT320211R2	Transistor 2SC2021
QM12	1	HT320211R2	Transistor 2SC2021
QM13	1	HT320211R2	Transistor 2SC2021
QM18	1	HD20011050	Diode 1S1555

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PM01-MISCELLANEOUS			
JM01	1	YP06001770	Plug (12P) 3022-12B
JM02	1	YP06001780	Plug (11P) 3022-11B
JM03	1	YP06001790	Plug 3022-0-9B
JM04	1	YP06001220	Plug (2P) 3022-2B
JM05	1	YP06001790	Plug (9P) 3022-9B
SM01	1	SC02030102	Switch, 3 Position
SM02	1	SC02020322	Switch, 2 Position
PP01-ROTARY SWITCH CIRCUIT BOARD			
PP01	1	YF47230102	P.W. Board, Rotary Switch
RP01-RESISTORS			
RP01	1	GD05271140	Resistor 270Ω ±5% ¼W
RP02	1	GD05102140	Resistor 1KΩ ±5% ¼W
RP03	1	GD05102140	Resistor 1KΩ ±5% ¼W
QP01-Photo Unit			
QP01	1	HW10001060	Photo Unit PS4001
QP02	1	HW10001060	Photo Unit PS4001
SP01-Rotary Switch, 24 Position			
SP01	1	SR24020010	Rotary Switch, 24 Position
PR01-RX CIRCUIT BOARD			
PR01	1	YF47850130	P.W. Board, RX
PR01-CAPACITORS			
C001	1	DK16471300	Ceramic 470pF ±10%
C002	1	DK16102300	Ceramic 0.001μF ±10%
C003	1	DK16102300	Ceramic 0.001μF ±10%
C004	1	DK16102300	Ceramic 0.001μF ±10%
C005	1	DD15200330	Ceramic 20pF ±5%
C006	1	DD15300330	Ceramic 30pF ±5%
C007	1	DK16102300	Ceramic 0.001μF ±10%
C008	1	DK16102300	Ceramic 0.001μF ±10%
C009	1	DK16102300	Ceramic 0.001μF ±10%
CR04	1	DK16102300	Ceramic 0.001μF ±10%
CR07	1	DD10005010	Ceramic 0.5pF 50V
CR08	1	DD10005030	Ceramic 5pF
CR09	1	DK16102300	Ceramic 0.001μF ±10%
CR10	1	DD11070330	Ceramic 7pF ±0.5pF
CR11	1	DD15240330	Ceramic 24pF ±5%
CR12	1	DK16102300	Ceramic 0.001μF ±10%
CR13	1	DK16102300	Ceramic 0.001μF ±10%
CR14	1	DK16102300	Ceramic 0.001μF ±10%
CR15	1	DC18202020	Feedthru 2000pF
CR16	1	CT10600030	Trimming 6pF
CR17	1	CT10600030	Trimming 6pF
CR18	1	CT10600030	Trimming 6pF
CR19	1	DD10005030	Ceramic 5pF ±0.25pF
CR20	1	DK16102300	Ceramic 0.001μF ±10%
CR21	1	DK16102300	Ceramic 0.001μF ±10%
CR22	1	DS17103010	Ceramic 0.01μF
CR23	1	EV10403560	Elect 0.1μF 35V
CR24	1	DS17103010	Semicon 0.01μF
CR25	1	DS17103010	Semicon 0.01μF
CR26	1	DS17103010	Semicon 0.01μF
CR27	1	DD15150330	Ceramic 15pF ±5%
CR28	1	DD15240330	Ceramic 24pF ±5%
CR29	1	DD10010300	Ceramic 1pF ±0.25pF

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
CR30	1	DK16122300	Ceramic 0.0012μF ±10%
CR31	1	DD10020300	Ceramic 2pF ±0.25pF
CR32	1	DK18103310	Ceramic 0.01μF
CR33	1	DD15820330	Ceramic 82pF ±5%
CR34	1	DD15201360	Ceramic 200pF ±5%
CR35	1	DD15360300	Ceramic 360pF ±5%
CR36	1	DS17683010	Semicon 0.068μF ±20%
CR37	1	DF16223300	Film 0.022μF ±10%
CR38	1	EA33601630	Elect 33μF 16V
CR39	1	DS17683010	Semicon 0.068μF ±20%
CR40	1	DS17683010	Semicon 0.068μF ±20%
CR41	1	DS17683010	Semicon 0.068μF ±20%
CR42	1	DS17683010	Semicon 0.068μF ±20%
CR43	1	DD15331360	Ceramic 330pF ±5%
CR44	1	DF16103300	Film 0.01μF ±10%
CR45	1	DK16221300	Ceramic 220pF ±10%
CR46	1	DK16102300	Ceramic 0.001μF ±10%
CR47	1	DS17683010	Semicon 0.068μF ±20%
CR48	1	DS17683010	Semicon 0.068μF ±20%
CR49	1	DS17683010	Semicon 0.068μF ±20%
CR50	1	DS17683010	Semicon 0.068μF ±20%
CR51	1	DS17473010	Semicon 0.047μF ±20%
CR52	1	DD15201360	Ceramic 200pF ±5%
CR53	1	DF16223300	Film 0.022μF ±10%
CR54	1	DF16103300	Film 0.01μF ±10%
CR55	1	DF16223300	Film 0.022μF ±10%
CR56	1	EV10403560	Elect 0.1μF 35V
CR57	1	EA10601690	Elect 10μF 16V
CR58	1	DF16472300	Film 0.0047μF ±10%
CR59	1	DF16472300	Film 0.0047μF ±10%
CR61	1	DD12100040	Ceramic 10pF ±1pF
CR62	1	DF16103300	Film 0.01μF ±10%
CR63	1	DD15331010	Ceramic 330pF ±5%
CR64	1	DD15201010	Ceramic 200pF ±5%
CR65	1	DF16103300	Film 0.01μF ±10%
CR66	1	EA22601090	Elect 22μF 10V
CR67	1	DF16223300	Film 0.022μF ±10%
CR68	1	DK16471300	Ceramic 470pF ±10%
CR70	1	EV33600660	Elect 33μF 6.3V
CR71	1	EV47501060	Elect 4.7μF 10V
CR72	1	DF16103300	Film 0.01μF ±10%
CR73	1	DF16223300	Film 0.022μF ±10%
CR74	1	DF16102300	Film 0.001μF ±10%
CR75	1	DF16223300	Film 0.022μF ±10%
CR76	1	DF16102300	Film 0.001μF ±10%
CR78	1	DF16223300	Film 0.022μF ±10%
CR80	1	DF16103300	Film 0.01μF ±10%
CR81	1	EA10601690	Elect 10μF 16V
CR82	1	DD15101350	Ceramic 100pF ±5%
CR83	1	EA10601690	Elect 10μF 16V
CR84	1	EA10601690	Elect 10μF 16V
CR85	1	DF16103300	Film 0.01μF ±10%
CR86	1	DK16102300	Ceramic 0.001μF ±10%
CR87	1	EV33502560	Elect 3.3μF 6.3V
CR88	1	EV15600660	Elect 15μF 16V
CR89	1	E010601620	Elect 10μF 16V
CR90	1	EE22701650	Elect 220μF 16V
CR91	1	DS17104010	Semicon 0.1μF ±20%
CR92	1	EA22702590	Elect 220μF 25V
CR93	1	EA10701090	Elect 100μF 10V
CR94	1	DF16563300	Film 0.056μF ±10%
CR95	1	EA10505090	Elect 1μF 50V
CR96	1	EA33601690	Elect 33μF 16V
CR99	1	DF16333300	Film 0.033μF ±10%

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PRO1-RESISTORS (All Resistors are ±5% and ¼W)			
RR02	1	GD05104140	100KΩ
RR03	1	GD05153140	15KΩ
RR04	1	GD05103140	10KΩ
RR05	1	GD05101140	100Ω
RR06	1	GD05470140	47Ω
RR07	1	GD05102140	1KΩ
RR08	1	GD05821140	820Ω
RR06	1	GD05223140	22KΩ
RR10	1	GD05104140	100KΩ
RR11	1	GD05104140	100KΩ
RR12	1	GD05683140	68KΩ
RR13	1	GD05123140	12KΩ
RR14	1	GD05101140	100Ω
RR15	1	GD05101140	100Ω
RR16	1	RA02030060	20KΩ Trimming
RR17	1	GD05473140	47KΩ
RR18	1	GD05562140	5.6KΩ
RR19	1	GD05473140	47KΩ
RR20	1	GD05562140	5.6KΩ
RR21	1	GD05470140	47Ω
RR22	1	GD05101140	100Ω
RR23	1	GD05222140	2.2KΩ
RR24	1	GD05222140	2.2KΩ
RR25	1	GD05123140	12KΩ
RR26	1	GD05472140	4.7KΩ
RR27	1	GD05102140	1KΩ
RR28	1	GD05101140	100Ω
RR30	1	GD05222140	2.2KΩ
RR31	1	GD05153140	15KΩ
RR32	1	GD05153140	15KΩ
RR33	1	GD05222140	2.2KΩ
RR34	1	GD05153140	15KΩ
RR35	1	GD05102140	1KΩ
RR36	1	GD05101140	100Ω
RR37	1	GD05101140	100Ω
RR38	1	GD05101140	100Ω
RR39	1	GD05152140	1.5KΩ
RR40	1	GD05152140	1.5KΩ
RR41	1	GD05101140	100Ω
RR42	1	GD05562140	5.6KΩ
RR43	1	GD05222140	2.2KΩ
RR44	1	GD05101140	100Ω
RR45	1	GD05152140	1.5KΩ
RR46	1	GD05102140	1KΩ
RR47	1	GD05102140	1KΩ
RR48	1	GD05103140	10KΩ
RR49	1	GD05103140	10KΩ
RR50	1	GD05562140	5.6KΩ
RR51	1	GD05333140	33KΩ
RR52	1	GD05474140	470KΩ
RR53	1	GD05102140	1KΩ
RR54	1	GD05121140	120Ω
RR55	1	GD05102140	1KΩ

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
RR56	1	GD05472140	4.7KΩ
RR57	1	GD05472140	4.7KΩ
RR60	1	GD05473140	47KΩ
RR61	1	RA01010080	100Ω Trimming
RR62	1	GD05222140	2.2KΩ
RR63	1	GD05473140	47KΩ
RR64	1	GD05222140	2.2KΩ
RR65	1	GD05472140	4.7KΩ
RR66	1	GD05333140	33KΩ
RR67	1	GD05153140	15KΩ
RR68	1	GD05101140	100Ω
RR70	1	RA04720090	4.7KΩ Trimming
RR71	1	GD05393140	39KΩ
RR72	1	GD05103140	10KΩ
RR73	1	GD05104140	100KΩ
RR74	1	GD05151140	150Ω
RR75	1	GD05102140	1KΩ
RR76	1	GD05333140	33KΩ
RR77	1	GD05562140	5.6KΩ
RR78	1	GD05102140	1.2KΩ
RR80	1	GD05221140	220Ω
RR81	1	GD05682140	6.8KΩ
RR82	1	GD05562140	5.6KΩ
RR83	1	GD05152140	1.5KΩ
RR84	1	GD05103140	10KΩ
RR98	1	GD05103140	10KΩ
RR99	1	RA01040260	100KΩ Trimming
PRO1-SEMICONDUCTORS			
QQ01	1	HF40048100	F.E.T. 3SK48
QQ02	1	HD50001060	Diode 15V77
QQ03	1	HD50001060	Diode 15V77
QR01	1	HF900041A0	F.E.T. 3N201(B)
QR02	1	HD20011050	Diode 1S1555
QR03	1	HD10001050	Diode 1N60
QR04	1	HF900041A0	F.E.T. 3N201(B)
QR05	1	HT304601B0	Transistor 2SC460(B)
QR06	1	HT304601B0	Transistor 2SC460(B)
QR07	1	HT304601B0	Transistor 2SC460(B)
QR08	1	HD10001050	Diode 1N60
QR09	1	HC10023060	IC μPC577H
QR10	1	HC10023060	IC μPC577H
QR11	1	HD10001050	Diode 1N60
QR12	1	HD10001050	Diode 1N60
QR13	1	HT309451Q0	Transistor 2SC945(Q)
QR14	1	HT309451Q0	Transistor 2SC945(Q)
QR15	1	HT309451Q0	Transistor 2SC945(Q)
QR16	1	HT309451Q0	Transistor 2SC945(Q)
QR17	1	HD10001050	Diode 1N60
QR18	1	HD10001050	Diode 1N60
QR19	1	HT309451Q0	Transistor 2SC945(B)
QR20	1	HC10031010	IC HA1368W
QR21	1	HD20011050	Diode 1S1555
QR22	1	HC10037050	IC TA7063P
QR23	1	HD10001050	Diode 1N60
QR24	1	HD10001050	Diode 1N60
QR25	1	HV00002060	Varistor VD1212
QR26	1	HD10001050	Diode 1N60
QR30	1	HD20011050	Diode 1S1555
QR31	1	HF200191B0	F.E.T. 2SK19TM(GR)
QR32	1	HD20011050	Diode 1S1555
AR33	1	HT107331R0	Transistor 2SA733(R)

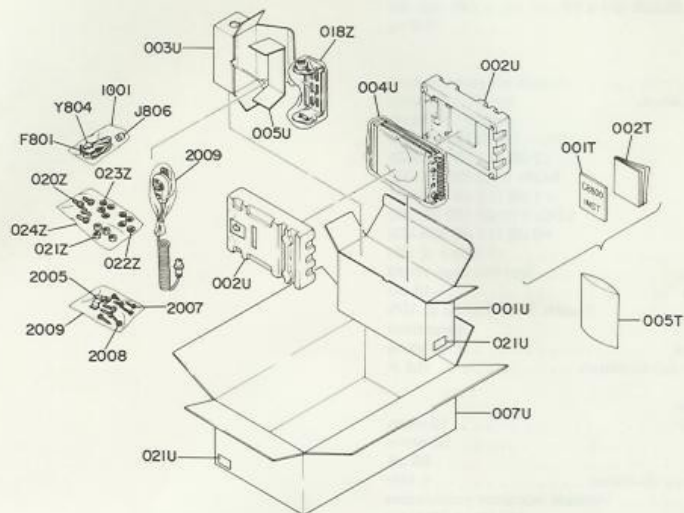
REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PR01-MISCELLANEOUS			
FR01	1	XU410700M5	Crystal Filter, 10.7MHz
FR02	1	FF11070050	Ceramic Filter, SFE10.7MA
FR03	1	FG455304F0	Ceramic Filter, CFU455F
FR04	1	FG455304F0	Ceramic Filter, CFU455F
FR05	1	XU410700M5	Crystal Filter, 10.7MHz
JR01	1	YP06000890	Plug (3P) 3022-03A
JR02	1	YP06001470	Plug (5P) 3094-05A
JR03	1	YP06000880	Plug
JR04	1	YT09010030	Terminal
JR05	1	YT09010030	Terminal
JR06	1	YT09010030	Terminal
JR07	1	YP06001150	Plug (8P) 3022-08A
JR08	1	YP06001480	Plug (2P) 5045-02A
JR09	1	YP10002160	Plug (2P) 5045-02A
JR10	1	YJ10000520	Jack (CTN-5)
JR11	1	YP06000890	Plug (3P) 3022-03A
LQ01	1	LA70280020	Ant. Coil, RF Pre-Amp.
LQ02	1	LA70190060	Ant. Coil, RF Pre-Amp.
LR01	1	LA70260010	Ant. Coil, RF Amp.
LR02	1	LA70260020	Ant. Coil, Local
LR03	1	3648121020	Link, Cavity Coil
LR04	1	3648121020	Link, Cavity Coil
LR05	1	3648121020	Link, Cavity Coil
LR06	1	LI70038090	I.F.T. Coil, IF
LR07	1	LI10010450	I.F.T. Coil
LR08	1	LI10010460	I.F.T. Coil
LR09	1	LC13940010	Choke Coil, 390μH
LR10	1	LC13940010	Choke Coil, 390μH
LR11	1	LC13940010	Choke Coil, 390μH
LR12	1	LC11040010	Choke Coil, 100μH
LR13	1	LI70038090	I.F.T. Coil, IF
LR14	1	LI70030390	I.F.T. Coil, IF
LR15	1	LC13940010	Choke Coil, 390μH
LR16	1	LC11050040	Choke Coil, 1mH
XR01	1	XZ41024505	Crystal 10.245MHz
PS01-POWER SUPPLY CIRCUIT BOARD			
PS01	1	YF47240090	P.W. Board, Power Supply
PS01-CAPACITORS			
CS01	1	DK18103310	Ceramic 0.01μF +100% -0
CS02	1	EA22601690	Elect 22μF 16V
CS03	1	DK18103310	Ceramic 0.01μF +100% -0
CS04	1	DK18103310	Ceramic 0.01μF +100% -0
PS01-RESISTORS			
RS01	1	GJ05201010	200Ω ±5% 1W
RS02	1	GD05561140	560Ω ±5% 1/4W
RS03	1	GJ05561010	560Ω ±5% 1W
PS01-SEMICONDUCTORS			
QS01	1	HT31368180	Transistor 2SC1368(B)
QS02	1	HD30017090	Zener B2090
QS03	1	HD20001210	Diode 1S2473
QS04	1	HT31368180	Transistor 2SC1368(B)
QS05	1	HD20001210	Diode 1S2473
QS06	1	HT70011100	Transistor JSP6009
QS07	1	HD20011050	Diode 1S1555
QS08	1	HD20011050	Diode 1S1555
QS10	1	HD20001210	Diode 1S2473

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PR01-PLUGS			
JS01	1	YP06002110	Plug (20P)
JS02	1	YP06000880	Plug (6P)
PT01-TX YOUNGER CIRCUIT BOARD			
PT01	1	YF47230120	P.W. Board, TX Younger
PT01-CAPACITORS			
CT01	1	DK18103310	Ceramic 0.01μF +100% -0
CT02	1	DD15690330	Ceramic 68pF ±5%
CT03	1	DD15200330	Ceramic 20pF ±5%
CT04	1	DD10015300	Ceramic 1.5pF ±0.25pF
CT05	1	DD15200330	Ceramic 20pF ±5%
CT06	1	DD15510330	Ceramic 51pF ±5%
CT07	1	DK18103310	Ceramic 0.01μF +100% -0
CT08	1	DK18103310	Ceramic 0.01μF +100% -0
CT09	1	DK18103310	Ceramic 0.01μF +100% -0
CT10	1	CT11050010	Trimming 12pF
CT11	1	DD10020300	Ceramic 2pF ±0.25pF
CT12	1	DK18103310	Ceramic 0.01μF +100% -0
CT13	1	DK18103310	Ceramic 0.01μF +100% -0
CT14	1	DK18103310	Ceramic 0.01μF +100% -0
CT15	1	CT11050010	Trimming 12pF
CT16	1	DD10020300	Ceramic 2pF ±0.25pF
CT17	1	DK18103310	Ceramic 0.01μF +100% -0
CT18	1	CT11050010	Trimming 12pF
CT19	1	DD10050300	Ceramic 5pF ±0.25pF
CT21	1	DD15820300	Ceramic 82pF ±5%
CT22	1	DD15200300	Ceramic 20pF ±5%
CT23	1	DK18103310	Ceramic 0.01μF +100% -0
CT24	1	EV47502560	Elect 4.7μF 25V
CT25	1	DK18103310	Ceramic 0.01μF +100% -0
CT26	1	CT11050010	Trimming 12pF
CT27	1	DD11100300	Ceramic 10pF ±0.5pF
CT28	1	DD15360300	Ceramic 36pF ±5%
CT30	1	EA10601690	Elect 10μF 16V
CT31	1	DD11100300	Ceramic 10pF ±0.5pF
PT01-RESISTORS			
(All Resistors are ±5% and 1/4W)			
RT01	1	GD05562140	5.6KΩ
RT02	1	GD05102140	1KΩ
RT03	1	GD05680140	68Ω
RT04	1	GD05101140	100Ω
RT05	1	GD05472140	4.7KΩ
RT06	1	GD05561140	560Ω
RT07	1	GD05100140	10Ω
RT08	1	GD05680140	68Ω
RT09	1	GD05121140	120Ω
RT10	1	GD05100140	10Ω
RT11	1	GD05220140	22Ω
RT14	1	GD05561140	560Ω
PT01-SEMICONDUCTORS			
QT01	1	HT32347100	Transistor 2SC2347
QT02	1	HT32347100	Transistor 2SC2347
QT03	1	HT30994100	Transistor 2SC994
QT04	1	HT321180A0	Transistor 2SC2118

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
PT01-MISCELLANEOUS			
JT01	1	YP06001200	Plug (5P)
JT02	1	YP06000890	Plug (3P)
LT01	1	LW10188010	Doublar Coil, RF
LT02	1	LW10188010	Doublar Coil, RF
LT03	1	LC16000010	Choke Coil (5T)
LT04	1	LC16000010	Choke Coil (5T)
LT05	1	LC16000010	Choke Coil (5T)
LT06	1	LC16000010	Choke Coil (5T)
LT07	1	LC17000010	Choke Coil (4T)
LT08	1	LC16000010	Choke Coil (5T)
LT09	1	LC16000010	Choke Coil (5T)
LT10	1	LC16000010	Choke Coil (5T)
PZ01-BACK-UP CIRCUIT BOARD			
PZ01	1	YF47230040	P.W. Board, Back-up
PZ01-CAPACITOR			
CZ01	1	EA10601690	Elect 10 μ F 16V
PZ01-RESISTORS (All Resistors are $\pm 5\%$ and $\frac{1}{4}W$)			
RZ01	1	GD05392140	3.9K Ω
RZ02	1	GD05562140	5.6K Ω
RZ03	1	GD05272140	2.7K Ω
RZ04	1	GD05823140	82K Ω
RZ05	1	GD05823140	82K Ω
RZ06	1	GD05102140	1K Ω
PZ01-SEMICONDUCTORS			
OZ01	1	HT107861R0	Transistor 2SA786(R)
OZ02	1	HT320211R2	Transistor 2SC2021LN
OZ03	1	HT106731B0	Transistor 2SA673(B)
OZ04	1	HD30033090	Zener WZ052
AZ01	1	ZK47230010	Unit, K DC-DC Converter
P100-CTN-5 CIRCUIT BOARD			
P001	1	YD37790020	P.W. Board, CTN-5
CAPACITORS			
C101	1	EV47501660	Elect 4.7 μ F, 16V
C102	1	EV33601060	Elect 33 μ F, 10V
C103	1	DF17333010	Film 0.033 μ F $\pm 20\%$
C104	1	DF66101010	Film 100pF $\pm 10\%$
C105	1	DF64272010	Film 2700pF $\pm 2\%$
C106	1	DF64272010	Film 2700pF $\pm 2\%$
C107	1	DF65432010	Film 4300pF $\pm 5\%$
C108	1	DF65242010	Film 2400pF $\pm 5\%$
C109	1	EM10402510	Elect 0.1 μ F, 25V 25V
C110	1	EW10601010	Elect 10 μ F, 10V 10V
C111	1	DD15500010	Ceramic 50pF $\pm 5\%$
C113	1	DK16471010	Ceramic 470pF $\pm 10\%$
RESISTORS			
R101	1	RC10471140	470 Ω $\pm 10\%$ $\frac{1}{4}W$
R102	1	GD05682140	6.8K Ω $\pm 5\%$ $\frac{1}{4}W$
R103	1	GD05103140	10K Ω $\pm 5\%$ $\frac{1}{4}W$
R105	1	GD05103140	10K Ω $\pm 5\%$ $\frac{1}{4}W$
R106	1	GD05183140	18K Ω $\pm 5\%$ $\frac{1}{4}W$
R107	1	GD05223140	22K Ω $\pm 5\%$ $\frac{1}{4}W$
R108	1	RA01040110	100K Ω Trimming
R109	1	GD05103140	10K Ω $\pm 5\%$ $\frac{1}{4}W$
R110	1	GD05103180	10K Ω $\pm 5\%$ 1/8W
R111	1	GD05272140	2.7K Ω $\pm 5\%$ $\frac{1}{4}W$

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
R112	1	GD05104140	100K Ω $\pm 5\%$ $\frac{1}{4}W$
R113	1	GD05472140	4.7K Ω $\pm 5\%$ $\frac{1}{4}W$
R114	1	GD05682180	6.8K Ω $\pm 5\%$ 1/8W
R115	1	GD05473140	47K Ω $\pm 5\%$ $\frac{1}{4}W$
R116	1	GD05392180	3.9K Ω $\pm 5\%$ 1/8W
R117	1	GD05182180	1.8K Ω $\pm 5\%$ 1/8W
R118	1	RA01030232	10K Ω Trimming
R119	1	GD05473140	47K Ω $\pm 5\%$ $\frac{1}{4}W$
R120	1	RA01040110	100K Ω Trimming
R121	1	GD05272180	2.7K Ω $\pm 5\%$ 1/8W
R122	1	GD05121180	120 Ω $\pm 5\%$ 1/8W
MISCELLANEOUS			
D101	1	HD20011050	Diode, 1S1555
J101	1	YP10001060	Plug
Q101	1	HT30828180	Transistor, 2SC828(C)
Q102	1	HT30828180	Transistor, 2SC828(C)
Q103	1	HT30828180	Transistor, 2SC828(C)
Q104	1	HT30828180	Transistor, 2SC828(C)
Q105	1	HT30828180	Transistor, 2SC828(C)
WW02	1	YB01000102	Connective Cord
WW03	1	YB01000580	Connective Cord
WW04	1	YB01000420	Connective Cord
WW05	1	YB01000430	Connective Cord
WW06	1	YB01000440	Connective Cord
WW07	1	YB01000152	Connective Cord
WW09	1	YB01000460	Connective Cord
WW10	1	YB01000470	Connective Cord
WW11	1	YB01000480	Connective Cord
WW12	1	YB01000490	Connective Cord
WW13	1	YB01000500	Connective Cord
WW14	1	YB01000510	Connective Cord
WW15	1	YB01000230	Connective Cord
WW17	1	YB00050040	Connective Cord
WW18	1	YB01000590	Connective Cord
WW20	1	YB01000270	Connective Cord
WW22	1	YB01000540	Connective Cord
WW23	1	YB01000550	Connective Cord
WW24	1	YB01000560	Connective Cord
(W01-99)	Assembly and Wiring		
(T01-99)	Adjustment		
(X01-00)	Correction		

10.6 PACKAGING



REF. DESIG.	QTY N	PART NO.	DESCRIPTION
001T	1	4785851010	Instructions
002T	1	4785856010	Circuit Diagram
005T	1	9013025010	Polyethy Bag
001U	1	4723801050	Packing Case
002U	2	4723809010	Cushion
003U	1	4723801020	Packing Case
004U	1	9013340010	Polyethy Bag
005U	1	4723803010	Partitioner
007U	1/5	4723805040	Master Carton
021U	3	9526019010	Serial No. Card
018Z	1	9011340010	Polyethy Bag
020Z	4	5203052089	H. Head Bolt, P. H5 x 20
021Z	4	5311050389	Hexagon Nut
022Z	4	5404050280	Spring Washer
023Z	4	5402050180	Flat Washer, P.
024Z	1	9011010010	Polyethy Bag

REF. DESIG.	QTY N	PART NO.	DESCRIPTION
1001	1	9010818010	Polyethy Bag
2005	1	4723155010	Hanger
2007	4	51400312X0	B.H. Tapped Screw B3 x 12
2008	4	51380330A0	P.H. Tapped Screw P3 x 30
2009	2	9010608010	Polyethy Bag
F801	1	FS10600010	Fuse 6A
Y804	1	YC01500022	A.C. Power Cord
J806	1	YP05000040	Plug, (9P)

11. TECHNICAL SPECIFICATIONS

General

Transmission/reception frequency band 144 MHz ~ 146 MHz
 Type of emission F3
 Microphone input impedance 600 ohms
 Speaker impedance 8 ohms
 Supply voltage 13.8 volts DC
 Dimensions . . . 168 mm (W) x 58 mm (H) x 240 mm (D)
 Weight 3.0 kg

Receiver section

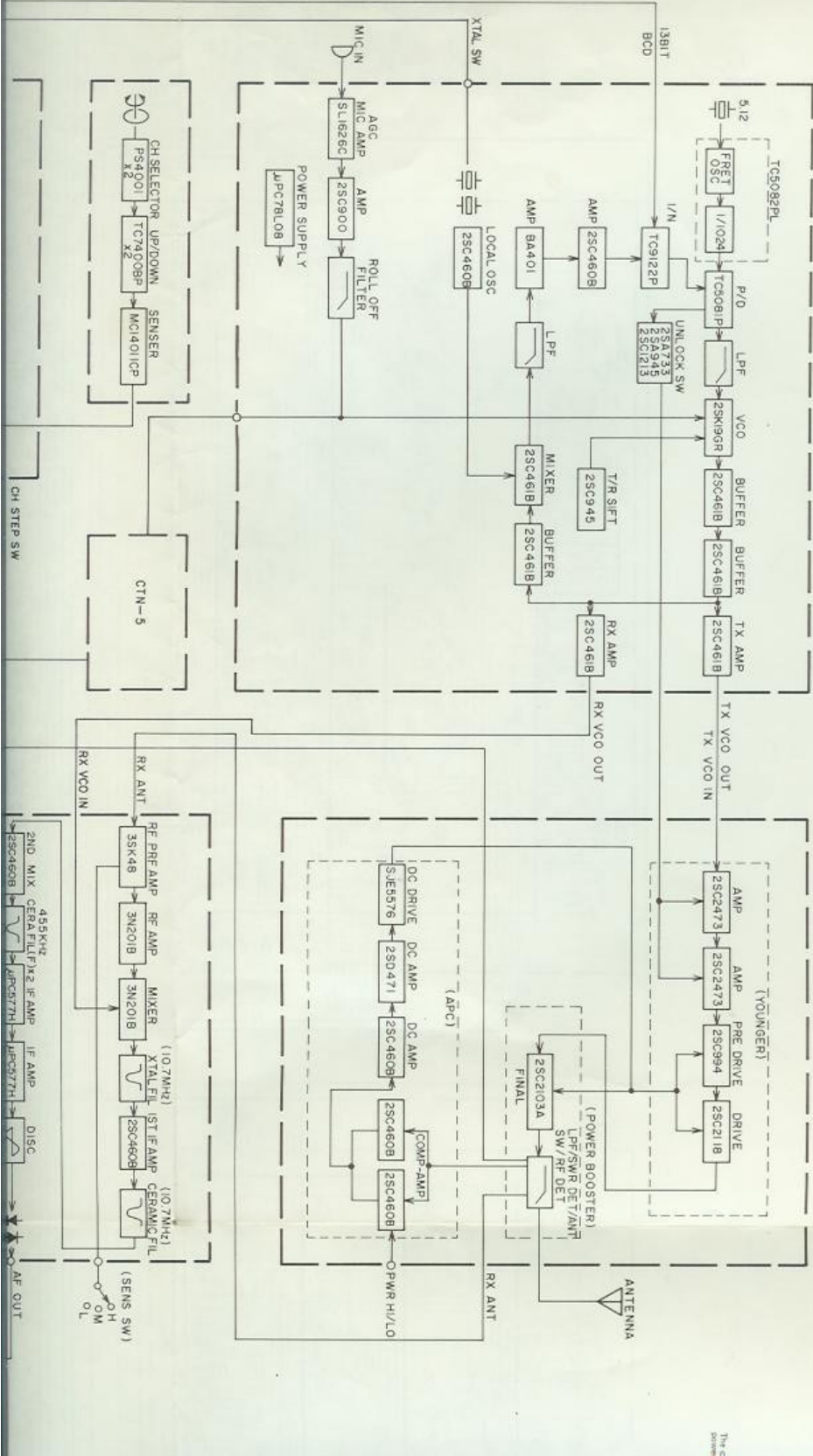
Reception system Double superheterodyne
 Intermediate frequencies 1st IF: 10.7 MHz
 2nd IF: 455 kHz
 Sensitivity DX: -10 dB (20 dB OS)
 -12 dB (12 dB SINAD)
 NOR: 0 dB (20 dB OS)
 -1 dB (12 dB SINAD)
 LOC: +10 dB (20 dB OS)
 +9 dB (12 dB SINAD)
 Pass bandwidth ±7 kHz (-6 dB)
 Sensitivity Not less than 70 dB
 Squelch sensitivity -15 dB
 AF output 2 watts (into 8 ohms at 10%
 distortion)
 AF load impedance 8 ohms
 Non-signal current consumption 0.6 A

Transmitter section

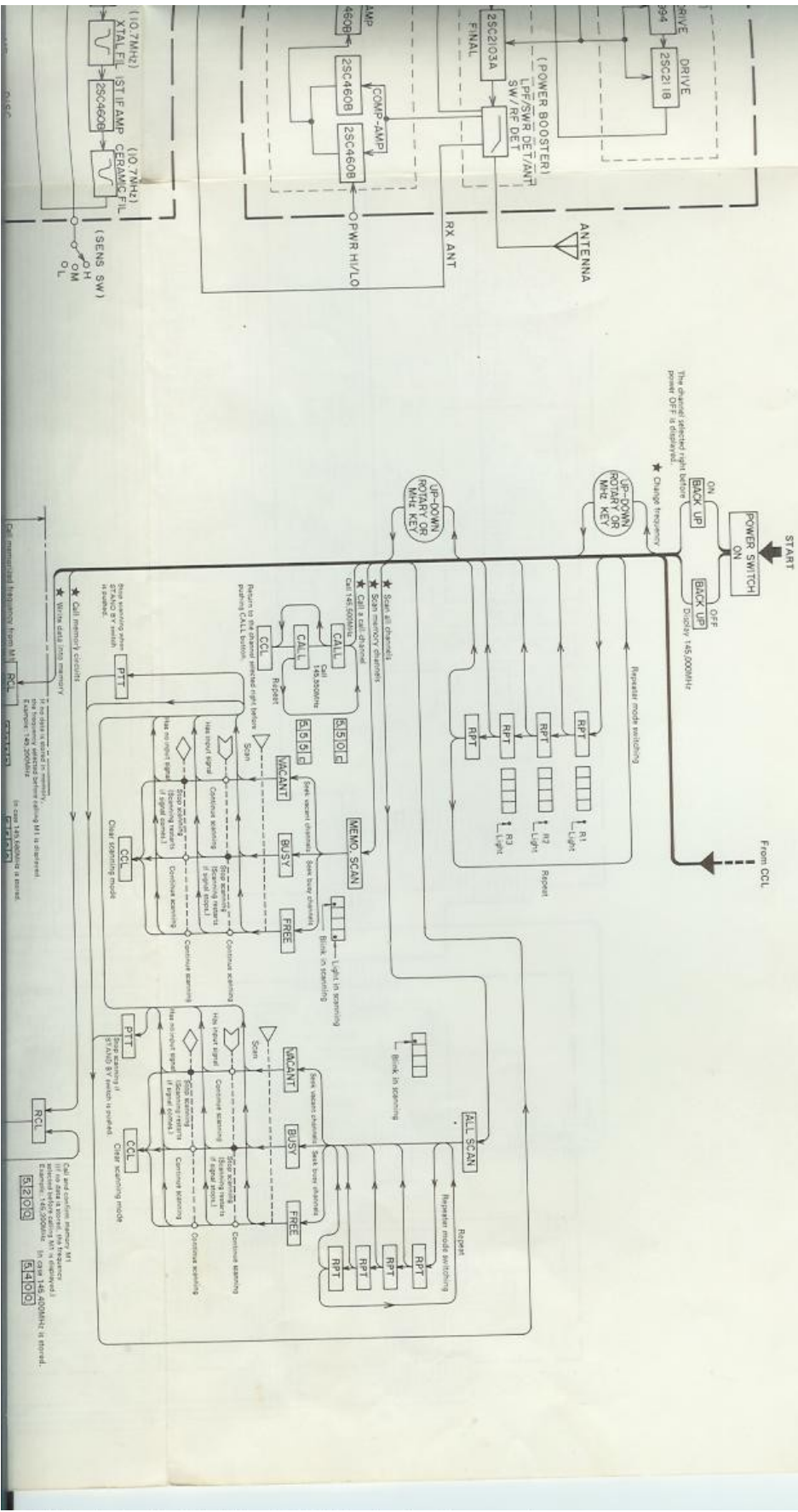
Transmission power 10 watts
 Load impedance 50 ohms
 Spurious ratio 65 dB
 Maximum frequency deviation 5 kHz
 Modulation Variable reactance modulation
 AF response 300 Hz to 3000 Hz
 Current consumption in transmission (Hi) 3.5 A

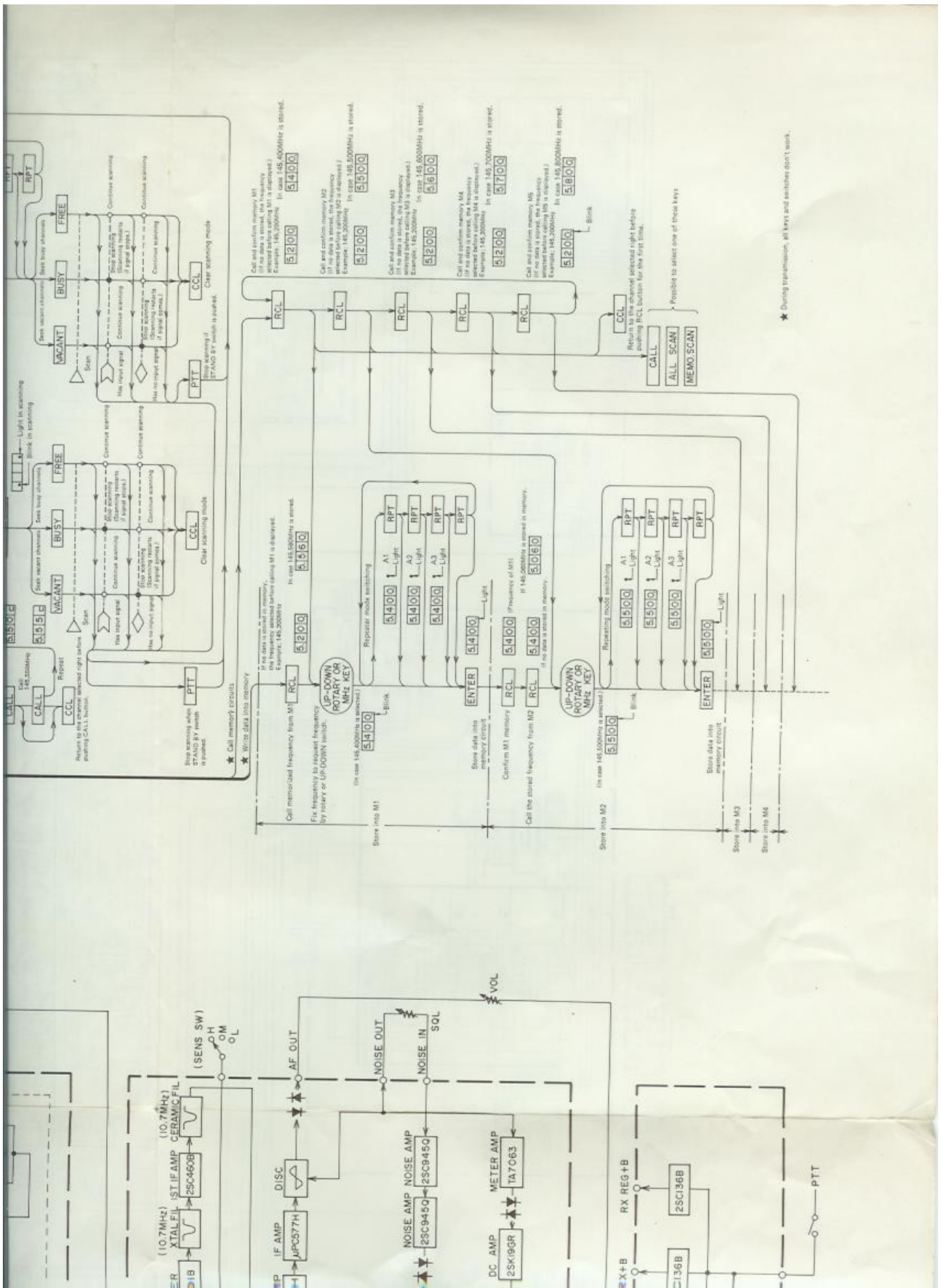
These specifications are a subject to change (in line with future improvements) without notice.

BLOCK DIAGRAM

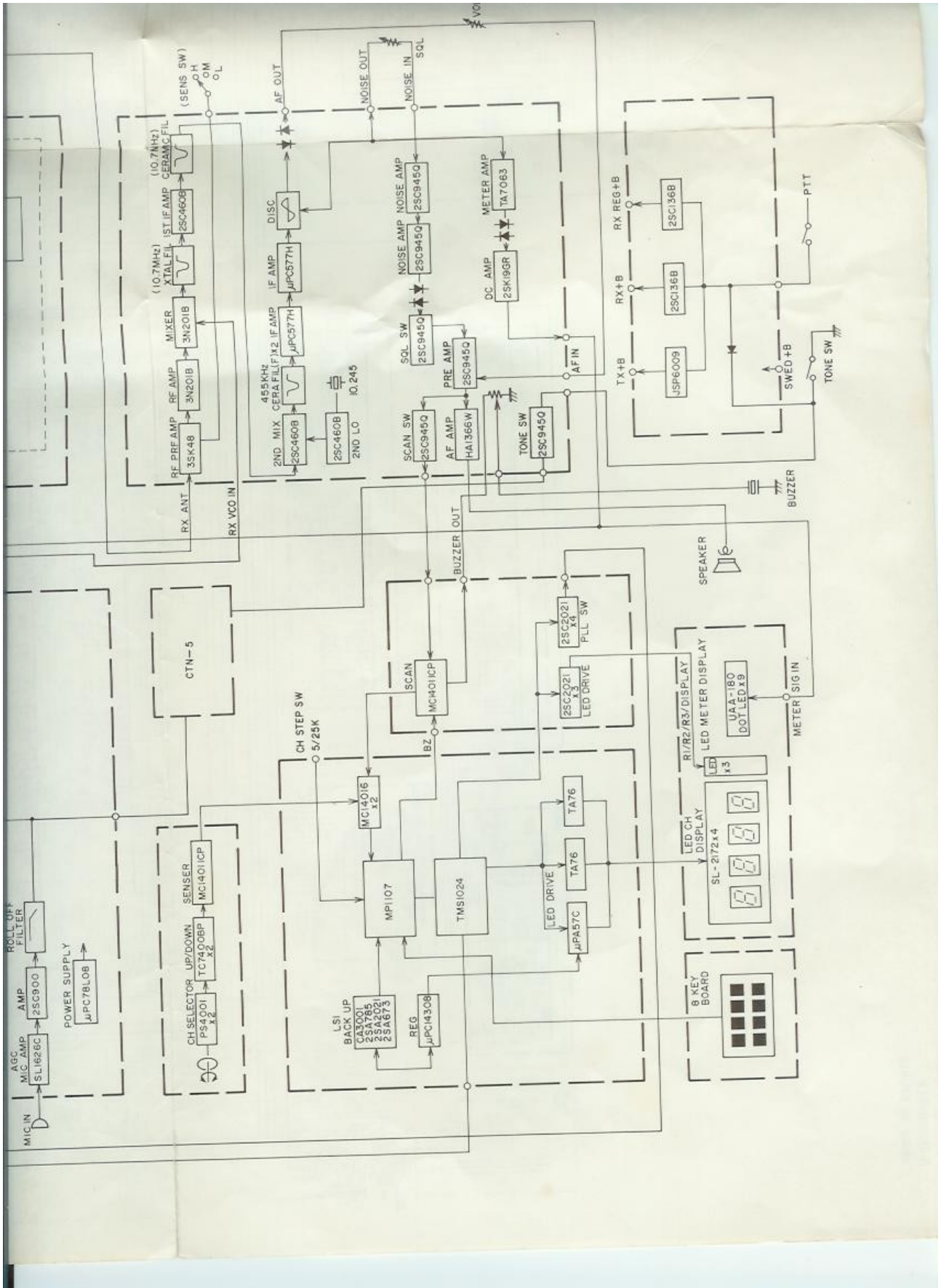


FLOW CHART





★ During transmission, all keys and switches don't work.



$$\begin{array}{l} \text{P } 1202 \\ \hline 6012.5 \end{array} = 5.002 \quad \begin{array}{l} \text{Mr T Jackson} \\ \text{Sunnyside} \\ \text{Reason Road} \\ \text{Stafford} \\ \text{ST17 9JT} \end{array} \quad \begin{array}{l} \text{P } 1202 \\ \hline 144.0125 - 138,000 \end{array}$$

$$5.002 \times 1024$$

$$IF = 5.122, 130 \text{ MHz}$$

$$1202 \times 5$$

$$+ 20 \times 5.002 \times 1200 = x -$$

$$(5.002 \times 1200) + 138,000 = 144,002.5$$

$$(144.0125 - 138,000) \div 5 = 1202.5$$

$$145.0125$$

$$(145.0125 - 138,000) \div 5 = 1402.5$$

$$(5.002 \times 1400) + 138,000 = 145,002.8$$

$$3.5 \text{ MHz @ } 145.975$$

$$2.5 \text{ MHz @ } 146.000$$